



Report No.: RZA2010-1426



ANSI C63.19 TEST REPORT

Product Name	CDMA 1X Digital Mobile Telephone
Model	HUAWEI M735
FCC ID	QISM735
Client	Huawei Technologies Co., Ltd.

TA Technology (Shanghai) Co., Ltd.



GENERAL SUMMARY

Product Name	CDMA 1X Digital Mobile Telephone	Model	HUAWEI M735
FCC ID	QISM735	Report No.	RZA2010-1426
Client	Huawei Technologies Co., Ltd.		
Manufacturer	Huawei Technologies Co., Ltd.		
Reference Standard(s)	ANSI C63.19-2007: American National Standard Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.		
Conclusion	<p>This portable wireless equipment has been measured in all cases requested by the relevant standards.</p> <p>General Judgment: M4 (RF Emission)</p> <div style="text-align: right;">  <p>(Stamp) Date of issue: September 16th, 2010</p> </div>		
Comment	The test result only responds to the measured sample.		

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1. General Information

1.1. Notes of the Test Report

TA Technology (Shanghai) Co., Ltd. guarantees the reliability of the data presented in this test report, which is the results of measurements and tests performed for the items under test on the date and under the conditions stated in this test report and is based on the knowledge and technical facilities available at TA Technology (Shanghai) Co., Ltd. at the time of execution of the test.

TA Technology (Shanghai) Co., Ltd. is liable to the client for the maintenance by its personnel of the confidentiality of all information related to the items under test and the results of the test. This report only refers to the item that has undergone the test.

This report standalone dose not constitute or imply by its own an approval of the product by the certification Bodies or competent Authorities. This report cannot be used partially or in full for publicity and/or promotional purposes without previous written approval of **TA Technology (Shanghai) Co., Ltd.** and the Accreditation Bodies, if it applies.

1.2. Testing Laboratory

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1.3. Applicant Information

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1.4. Manufacturer Information

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1.5. Information of EUT

General Information

Device Type:	Portable Device		
Product Name:	CDMA 1X Digital Mobile Telephone		
S/N:	7N9MAC1081100734		
Antenna Type:	Internal Antenna		
Device Operating Configurations:			
Operating Mode(s):	CDMA Cellular (tested)		
	CDMA PCS (tested)		
	CDMA AWS (tested)		
Test Modulation:	QPSK		
Operating Frequency Range(s):	Band	Tx (MHz)	Rx (MHz)
	CDMA Cellular	824.7 ~ 848.31	869.7 ~ 893.31
	CDMA PCS	1851.25 ~ 1908.75	1931.25 ~ 1988.75
	CDMA AWS	1711.25 ~ 1752.5	2111.25 ~ 2152.5
Test Channel: (Low - Middle - High)	1013 - 384 - 777	(CDMA Cellular)	(tested)
	25 - 600 - 1175	(CDMA PCS)	(tested)
	25 - 450 - 850	(CDMA AWS)	(tested)
Power Class:	CDMA Cellular: Tested with Power Control All up bits		
	CDMA PCS: Tested with Power Control All up bits		
	CDMA AWS: Tested with Power Control All up bits		
Hardware Version:	Ver.B		
Software Version:	M735C45B210		

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Auxiliary Equipment Details

AE1:Battery

Model: HB5I1H
Manufacturer: Huawei Technologies Co., Ltd.
SN: UNHA713X82800158

AE2:Travel Adapter

Model: HS-050040U5
Manufacturer: Huawei Technologies Co., Ltd.
SN: HKAA51024082

Equipment Under Test (EUT) is a model of CDMA 1X Digital Mobile Telephone with internal antenna. The detail about Mobile phone, Lithium Battery and AC/DC Adapter is in chapter 1.5 in this report. SAR is tested for CDMA Cellular, CDMA PCS and CDMA AWS.

The sample under test was selected by the Client.

Components list please refer to documents of the manufacturer.

1.6. The Ambient Conditions during Test

Temperature	Min. = 18°C, Max. = 28 °C
Relative humidity	Min. = 0%, Max. = 80%
Ground system resistance	< 0.5 Ω
Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.	

1.7. The Total M-rating of each tested band

Band	Rating
CDMA Cellular	M4
CDMA PCS	M4
CDMA AWS	M4

1.8. Test Date

The test is performed on September 12, 2010.

2. Test Information

2.1. Operational Conditions during Test

2.1.1. General Description of Test Procedures

The phone was tested in all normal configurations for the ear use. The EUT is mounted in the device holder equivalent as for classic dosimeter measurements. The acoustic output of the EUT shall coincide with the center point of the area formed by the dielectric wire and the middle bar of the arch's top frame. The EUT shall be moved vertically upwards until it touches the frame. The fine adjustment is possible by sliding the complete. EUT holder on the yellow base plate of the Test Arch phantom. These test configurations are tested at the high, middle and low frequency channels of each applicable operating mode; for example, GSM, WCDMA (UMTS), CDMA and TDMA.

2.1.2. CDMA Test Configuration

A communication link is set up with a System Simulator (SS) by air link, and a call is established. The Absolute Radio Frequency Channel Number (ARFCN) are allocated to 1013, 384 and 777 respectively in the case of CDMA Cellular, allocated to 25, 600 and 1175 respectively in the case of CDMA PCS, allocated to 25, 450 and 850 respectively in the case of CDMA AWS, The EUT is commanded to operate at maximum transmitting power.

Test Parameter setup for maximum RF output power according to section 4.4.5 of 3GPP2.

Parameter	Units	Value
I or	dBm/1.23MHz	-104
PilotE c /I or	dB	-7
TrafficE c /I or	dB	-7.4

2.2. HAC RF Measurements System Configuration

2.2.1. HAC Measurement Set-up

These measurements are performed using the DASY4 automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. Cell controller systems contain the power supply, robot controller, teach pendant (Joystick) and remote control, and are used to drive the robot motors. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit performs the signal amplification; signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

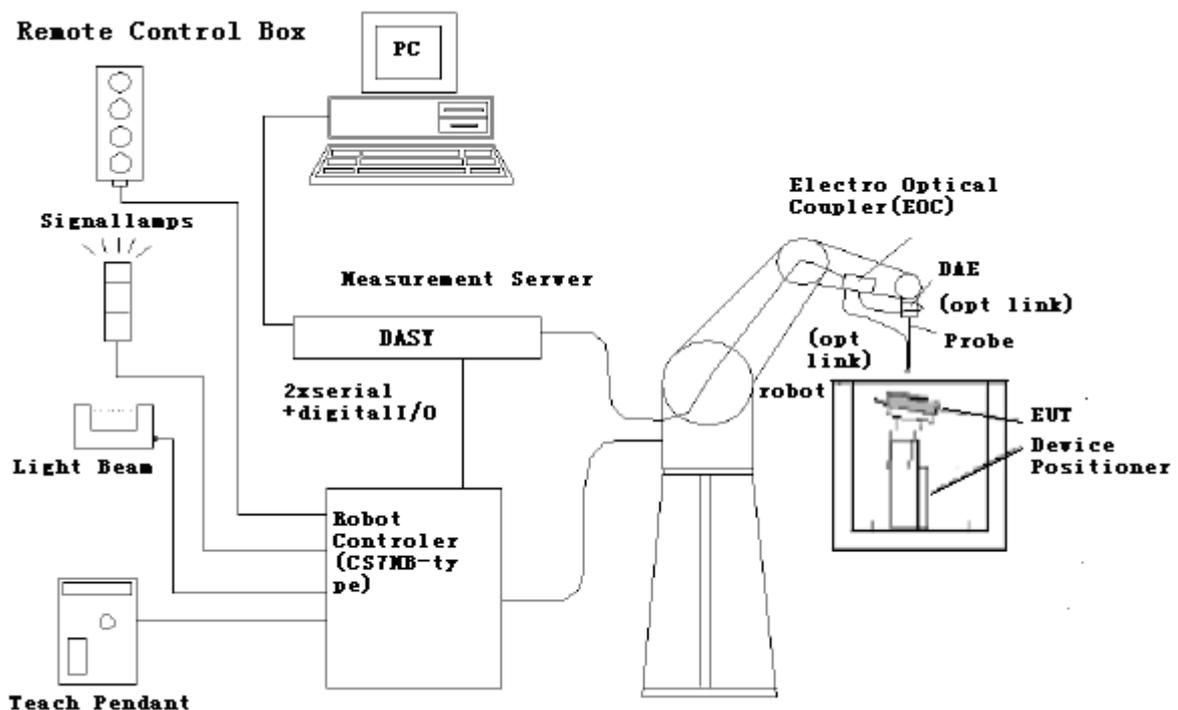


Figure 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

2.2.2. Probe System

The HAC measurements were conducted with the E-Field Probe ER3DV6 and the H-Field Probe H3DV6 (manufactured by SPEAG), designed in the classical triangular configuration and optimized for dosimetric evaluation.

E-Field Probe Description

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Calibration	In air from 100 MHz to 3.0 GHz (absolute accuracy $\pm 6.0\%$, $k=2$)
Frequency	40 MHz to > 6 GHz (can be extended to < 20 MHz) Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm (Tip: 16 mm) Tip diameter: 8 mm (Body: 12 mm) Distance from probe tip to dipole centers: 2.5 mm
Application	General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms



Figure 2 ER3DV6 E-field Probe

H-Field Probe Description

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether)
Frequency	200 MHz to 3 GHz (absolute accuracy $\pm 6.0\%$, $k=2$); Output linearized
Directivity	± 0.2 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
E-Field Interference	< 10% at 3 GHz (for plane wave)
Dimensions	Overall length: 330 mm (Tip: 40 mm) Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm



Figure 3 H3DV6 H-field Probe

Application General magnetic near-field measurements up to 3
 GHz (in air or liquids)
 Field component measurements
 Surface current measurements
 Low interaction with the measured field

2.2.3. Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: 370 x 370 x 370 mm).

The Device reference point is set for the EUT at 6.3 mm, the Grid reference point is on the upper surface at the origin of the coordinates, and the “user point \Height Check 0.5 mm” is 0.5mm above the center, allowing verification of the gap of 0.5mm while the probe is positioned there.

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.

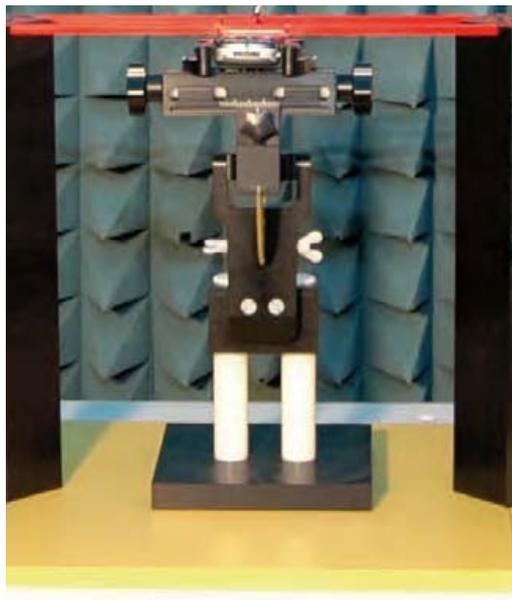


Figure 4 HAC Phantom & Device Holder

2.3. RF Test Procedures

The evaluation was performed with the following procedure:

1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
2. Position the WD in its intended test position. The gauge block can simplify this positioning. Note that a separate E-field and H-field gauge block will be needed if the center of the probe sensor elements is at different distances from the tip of the probe.
3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
4. The center sub-grid shall center on the center of the axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the 50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
5. Record the reading.
6. Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
7. Identify the five contiguous sub-grids around the center sub-grid with the lowest maximum field strength readings. Thus the six areas to be used to determine the WD's highest emissions are identified and outlined for the final manual scan. Please note that a maximum of five blocks can be excluded for both E-field and H-field measurements for the WD output being measured. Stated another way, the center sub-grid and three others must be common to both the E-field and H-field measurements.
8. Identify the maximum field reading within the non-excluded sub-grids identified in Step 7.
9. Convert the maximum field strength reading identified in Step 8 to V/m or A/m, as appropriate. For probes which require a probe modulation factor, this conversion shall be done using the appropriate probe modulation factor and the calibration.
10. Repeat Step 1 through Step 10 for both the E-field and H-field measurements.
11. Compare this reading to the categories in ANSI C63.19 Clause 7 and record the resulting category. The lowest category number listed in 7.2, Table 7.4, or Table 7.5 obtained in Step 10 for either E- or H-field determines the M category for the audio coupling mode assessment. Record the WD category rating.



Figure 5 WD reference and plane for RF emission measurements

2.4. System Check

Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 D.5 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical and magnetic output. Position the E-field and H-field probes so that:

The probes and their cables are parallel to the coaxial feed of the dipole antenna.

The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions.

The center point of the probe element(s) are 10 mm from the closest surface of the dipole elements. Validation was performed to verify that measured E-field and H-field values are within +/-25% from the target reference values provided by the manufacturer. "Values within +/-25% are acceptable. Of which 12% is deviation and 13% is measurement uncertainty."

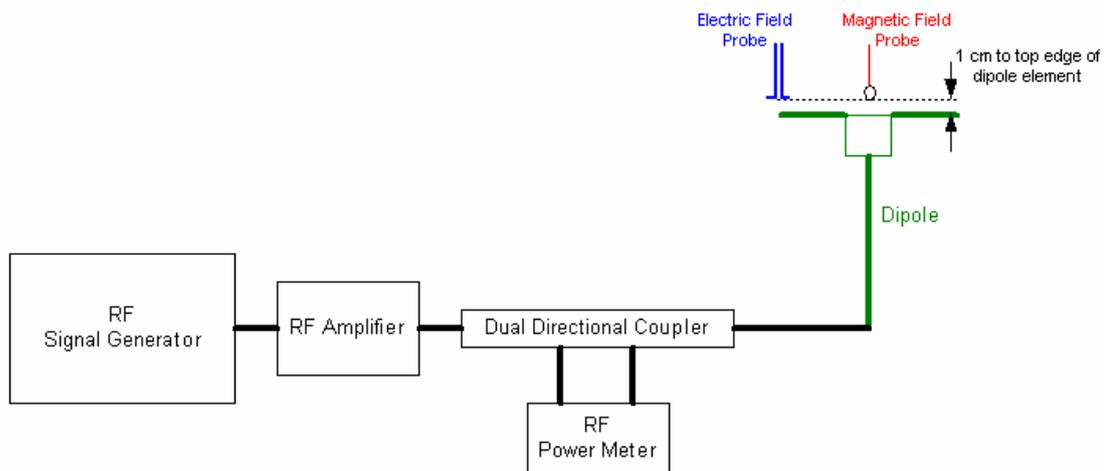


Figure 6 Dipole Validation Setup

Dipole Measurement Summary

E-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Measured ¹ Value(V/m)	Target ² Value(V/m)	Deviation ³ (%)	Test Date
CW	835	100	149.2	170.7	12.60	June 22, 2010
CW	1880	100	131.4	142.9	8.05	June 22, 2010
F-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Measured Value(A/m)	Target Value(A/m)	Deviation (%)	Test Date
CW	835	100	0.443	0.465	4.73	June 22, 2010
CW	1880	100	0.449	0.475	5.47	June 22, 2010

Notes: 1. please refer to the attachment for detailed measurement data and plot.

2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.

3. Deviation (%) = 100 * (Target value minus Measured value) divided by Target value.

2.5. Probe Modulation Factor

The Probe Modulation Factor (PMF) is defined as the ratio of the field readings for a CW and a modulated signal with the equivalent Field Envelope Peak as defined in ANSI C63.19 (Chapter C.3.1). Calibration shall be made of the modulation response of the probe and its instrumentation chain. This Calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type.

Modulation Factor Test Procedure

This may be done using the following procedure:

1. Fix the field probe in a set location relative to a field generating device, such as the reference dipole antenna.
2. Illuminate the probe using the wireless device connected to the reference dipole with a test signal at the intended measurement frequency, Ensure there is sufficient field coupling between the probe and the antenna so the resulting reading is greater than 10 dB above the probe system noise floor but within the systems operating range.
3. Record the amplitude applied to the antenna during transmission and the field strength measured by the E-field probe located near the tip of the dipole antenna
4. Replace the wireless device with an RF signal generator producing an unmodulated CW signal and set to the wireless device operating frequency.
5. Set the amplitude of the unmodulated signal to equal that recorded from the wireless device.
6. Record the reading of the probe measurement system of the unmodulated signal.
7. The ratio, in linear units, of the probe reading in Step 6 to the reading in Step 3 is the E-field modulation factor. $PMF_E = E_{CW} / E_{mod}$ ($PMF_H = H_{CW} / H_{mod}$)
8. Repeat the previous steps using the H-field probe, except locate the probe at the center of the dipole.

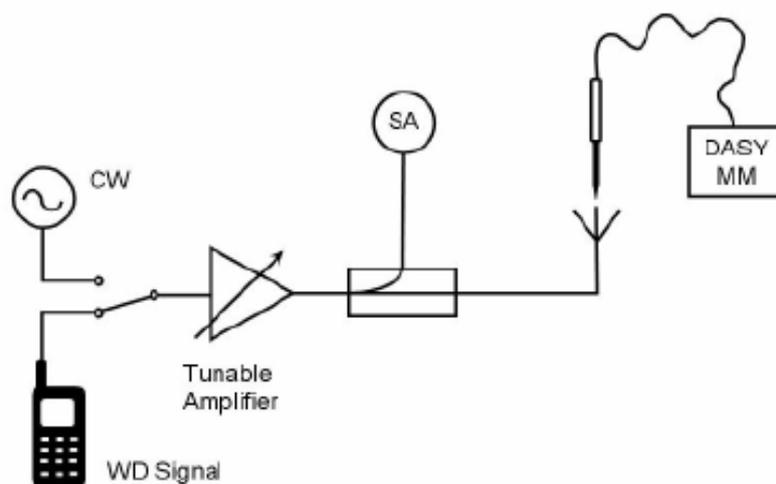


Figure Figure 7 Probe Modulation Factor Test Setup

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PMF

Band	E-Field Probe Modulation Factor	H-Field Probe Modulation Factor
CDMA Cellular	1.05	1.01
CDMA PCS	1.03	1.00
CDMA AWS	1.03	1.00

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2.6. Conducted Output Power Measurement

Summary

The DUT is tested using an E5515C communications tester as controller unit to set test channels and maximum output power to the DUT, as well as for measuring the conducted power. Conducted output power was measured using an integrated RF connector and attached RF cable. This result contains conducted output power for the EUT.

Conducted Power Results

CDMA Cellular (RC3)	Conducted Power (dBm)		
	Channel 1013	Channel 384	Channel 777
Before test	24.3	24.2	24.4
After test	24.3	24.3	24.2
CDMA Cellular (RC1)	Conducted Power (dBm)		
	Channel 1013	Channel 384	Channel 777
Before test	24.2	24.3	24.3
After test	24.4	24.3	24.4
CDMA PCS (RC3)	Conducted Power (dBm)		
	Channel 25	Channel 600	Channel 1175
Before test	24.2	24.3	24.4
After test	24.2	24.2	24.3
CDMA PCS (RC1)	Conducted Power (dBm)		
	Channel 25	Channel 600	Channel 1175
Before test	24.4	24.3	24.2
After test	24.1	24.3	24.4
CDMA AWS (RC3)	Conducted Power (dBm)		
	Channel 25	Channel 450	Channel 850
Before test	24.2	24.3	24.2
After test	24.3	24.1	24.2
CDMA AWS (RC1)	Conducted Power (dBm)		
	Channel 25	Channel 450	Channel 850
Before test	24.3	24.4	24.2
After test	24.2	24.2	24.3

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3. Test Results

3.1. ANSI C63.19-2007 Limits

Category		Telephone RF parameters < 960 MHz			
Near field	AWF	E-field emissions		H-field emissions	
Category M1/T1	0	631.0 to 1122.0	V/m	1.91 to 3.39	A/m
	-5	473.2 to 841.4	V/m	1.43 to 2.54	A/m
Category M2/T2	0	354.8 to 631.0	V/m	1.07 to 1.91	A/m
	-5	266.1 to 473.2	V/m	0.80 to 1.43	A/m
Category M3/T3	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M4/T4	0	< 199.5	V/m	< 0.60	A/m
	-5	< 149.6	V/m	< 0.45	A/m
Category		Telephone RF parameters > 960 MHz			
Near field	AWF	E-field emissions		H-field emissions	
Category M1/T1	0	199.5 to 354.8	V/m	0.60 to 1.07	A/m
	-5	149.6 to 266.1	V/m	0.45 to 0.80	A/m
Category M2/T2	0	112.2 to 199.5	V/m	0.34 to 0.60	A/m
	-5	84.1 to 149.6	V/m	0.25 to 0.45	A/m
Category M3/T3	0	63.1 to 112.2	V/m	0.19 to 0.34	A/m
	-5	47.3 to 84.1	V/m	0.14 to 0.25	A/m
Category M4/T4	0	< 63.1	V/m	< 0.19	A/m
	-5	< 47.3	V/m	< 0.14	A/m

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3.2. Summary Test Results

CDMA Cellular Results

E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
777	848.31	72.80	-0.091	M4	Figure 12
384	836.52	69.50	-0.130	M4	Figure 13
1013	824.70	72.30	0.034	M4	Figure 14
H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
777	848.31	0.105	-0.152	M4	Figure 15
384	836.52	0.096	-0.015	M4	Figure 16
1013	824.70	0.099	0.010	M4	Figure 17

CDMA PCS Results

E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
1175	1908.75	38.60	-0.099	M4	Figure 18
600	1880	38.80	-0.023	M4	Figure 19
25	1851.25	39.30	0.067	M4	Figure 20
H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
1175	1908.75	0.094	0.001	M4	Figure 21
600	1880	0.093	0.050	M4	Figure 22
25	1851.25	0.099	-0.116	M4	Figure 23

CDMA AWS Results

E-Field					
Channel	Frequency (MHz)	Peak Field (V/m)	Power Drift (dB)	Rating	Graph Results
850	1752.5	30.80	-0.064	M4	Figure 24
450	1732.5	31.30	0.052	M4	Figure 25
25	1711.25	26.60	-0.064	M4	Figure 26
H-Field					
Channel	Frequency (MHz)	Peak Field (A/m)	Power Drift (dB)	Rating	Graph Results
850	1752.5	0.073	0.166	M4	Figure 27
450	1732.5	0.074	0.072	M4	Figure 28
25	1711.25	0.066	-0.154	M4	Figure 29

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4. Measurement Uncertainty

No.	Error source	Type	Uncertainty Value (%)	Prob. Dist.	k	c_{iE}	c_{iH}	Standard Uncertainty (%) u_i (%) E	Standard Uncertainty (%) u_i (%) H	Degree of freedom V_{eff} or v_i
Measurement System										
1	Probe Calibration	B	5.	N	1	1	1	5.1	5.1	∞
2	Axial Isotropy	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
3	Sensor Displacement	B	16.5	R	$\sqrt{3}$	1	0.145	9.5	1.4	∞
4	Boundary Effects	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞
5	Linearity	B	4.7	R	$\sqrt{3}$	1	1	2.7	2.7	∞
6	Scaling to Peak Envelope Power	B	2.0	R	$\sqrt{3}$	1	1	1.2	1.2	∞
7	System Detection Limit	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
8	Readout Electronics	B	0.3	N	1	1	1	0.3	0.3	∞
9	Response Time	B	0.8	R	$\sqrt{3}$	1	1	0.5	0.5	∞
10	Integration Time	B	2.6	R	$\sqrt{3}$	1	1	1.5	1.5	∞
11	RF Ambient Conditions	B	3.0	R	$\sqrt{3}$	1	1	1.7	1.7	∞
12	RF Reflections	B	12.0	R	$\sqrt{3}$	1	1	6.9	6.9	∞
13	Probe Positioner	B	1.2	R	$\sqrt{3}$	1	0.67	0.7	0.5	∞
14	Probe Positioning	A	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
15	Extra. And Interpolation	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
Test Sample Related										
16	Device Positioning Vertical	B	4.7	R	$\sqrt{3}$	1	0.67	2.7	1.8	∞
17	Device Positioning Lateral	B	1.0	R	$\sqrt{3}$	1	1	0.6	0.6	∞
18	Device Holder and Phantom	B	2.4	R	$\sqrt{3}$	1	1	1.4	1.4	∞

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19	Power Drift	B	5.0	R	$\sqrt{3}$	1	1	2.9	2.9	∞
Phantom and Setup related										
20s	Phantom Thickness	B	2.4	R	$\sqrt{3}$	1	0.67	1.4	0.9	∞
Combined standard uncertainty(%)								14.7	10.9	
Expanded uncertainty (confidence interval of 95 %)		$u_e = 2u_c$		N	k=2			29.4	21.8	

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5. Main Test Instruments

No.	Name	Type	Serial Number	Calibration Date	Valid Period
01	Power meter	Agilent E4417A	GB41291714	March 13, 2010	One year
02	Power sensor	Agilent 8481H	MY41091316	March 26, 2010	One year
03	Signal Generator	HP 8341B	2730A00804	September 13, 2009	One year
04	Amplifier	IXA-020	0401	No Calibration Requested	
05	BTS	E5515C	MY48360988	December 4, 2009	One year
06	E-Field Probe	ER3DV6	2428	October 20, 2009	One year
07	H-Field Probe	H3DV6	6260	October 20, 2009	One year
08	DAE	DAE4	871	November 11, 2009	One year
09	Validation Kit 835MHz	CD835V3	1149	January 12, 2010	One year
10	Validation Kit 1880MHz	CD1880V3	1135	January 13, 2010	One year

*****END OF REPORT BODY*****

ANNEX A: System Check Results

HAC_System Performance Check at 835MHz_E

DUT: Dipole 835 MHz; Type: CD835V3; SN:1149

Date/Time: 9/12/2010 6:36:32 PM

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5 °C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 149.2 V/m

Probe Modulation Factor = 1.00

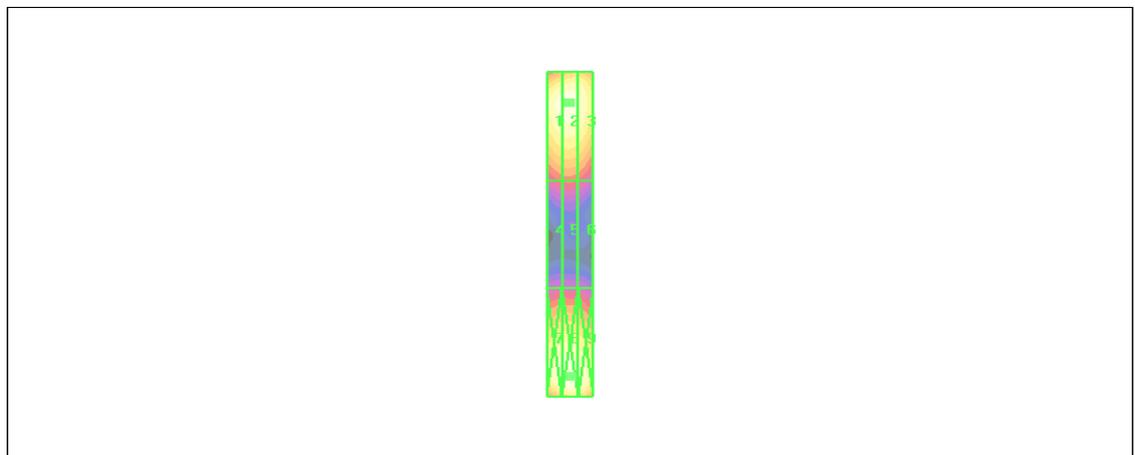
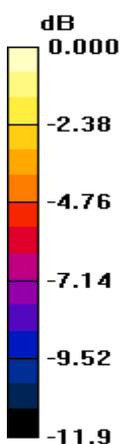
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 100.7 V/m; Power Drift = -0.066 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 147.0 M4	Grid 2 149.2 M4	Grid 3 143.9 M4
Grid 4 83.4 M4	Grid 5 85.0 M4	Grid 6 81.1 M4
Grid 7 148.8 M4	Grid 8 154.0 M4	Grid 9 148.9 M4



0 dB = 154.0V/m

Figure 8 System Performance Check 835MHz_E

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HAC_System Performance Check at 835MHz_H

DUT: Dipole 835 MHz; Type: CD835V3; SN: 1149

Date/Time: 9/12/2010 5:13:58 PM

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5 °C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260 ; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.443 A/m

Probe Modulation Factor = 1.00

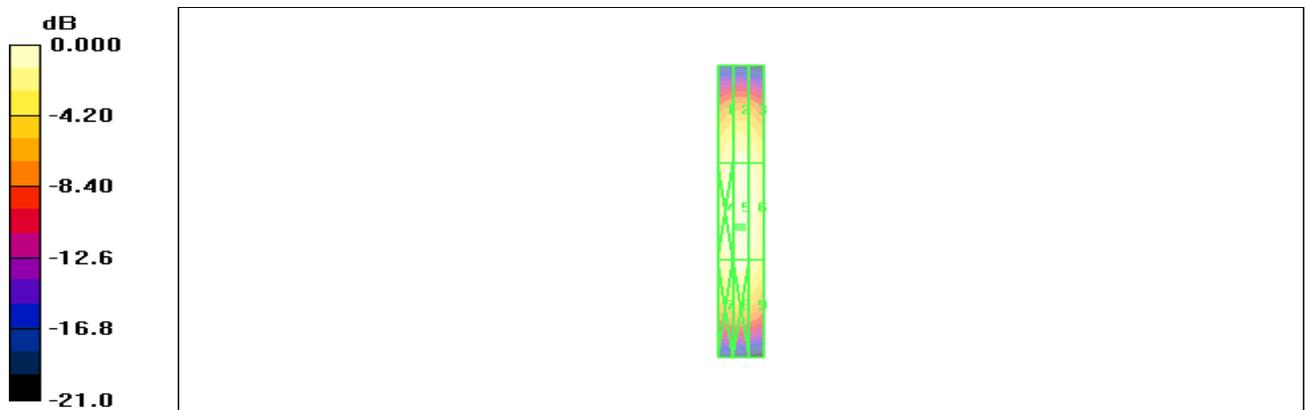
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.464 A/m; Power Drift = 0.019 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.391 M4	Grid 2 0.408 M4	Grid 3 0.384 M4
Grid 4 0.427 M4	Grid 5 0.443 M4	Grid 6 0.414 M4
Grid 7 0.397 M4	Grid 8 0.410 M4	Grid 9 0.381 M4



0 dB = 0.443A/m

Figure 9 System Performance Check 835MHz_H

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HAC_System Performance Check at 1880MHz_E

DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1135

Date/Time: 9/12/2010 3:46:34 PM

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5 °C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 131.4 V/m

Probe Modulation Factor = 1.00

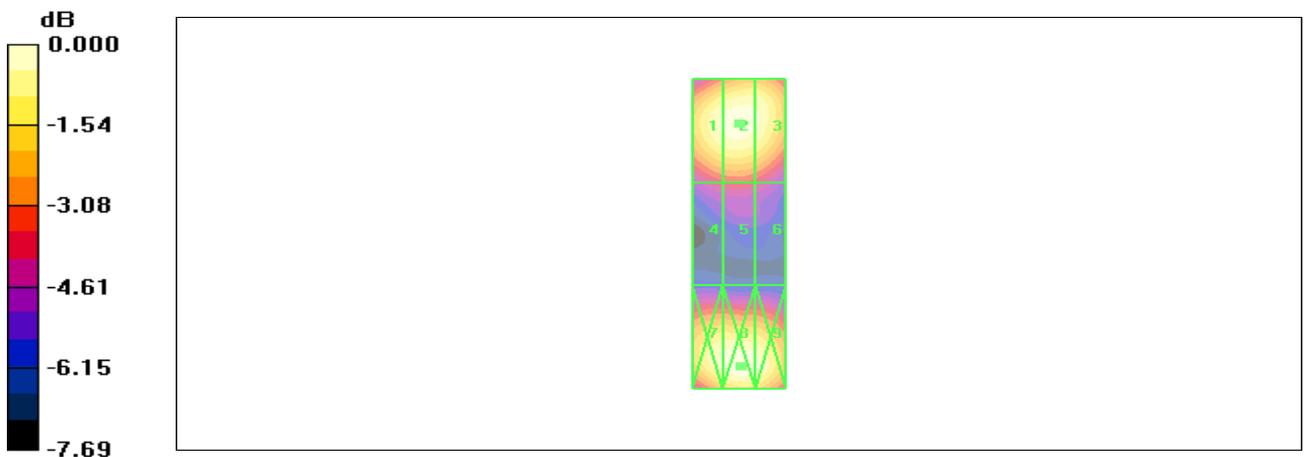
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 151.0 V/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 128.5 M2	Grid 2 131.4 M2	Grid 3 128.5 M2
Grid 4 87.5 M3	Grid 5 89.7 M3	Grid 6 86.2 M3
Grid 7 128.7 M2	Grid 8 134.0 M2	Grid 9 130.3 M2



0 dB = 134.0V/m

Figure 10 System Performance Check 1880MHz_E

TA Technology (Shanghai) Co., Ltd. Test Report

HAC_System Performance Check at 1880MHz_H

DUT: Dipole 1880 MHz; Type: CD1880V3; SN:1135

Date/Time: 9/12/2010 2:20:22 PM

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liqid Temperature: 21.5 °C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to Dipole = 10mm/Hearing Aid

Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.449 A/m

Probe Modulation Factor = 1.00

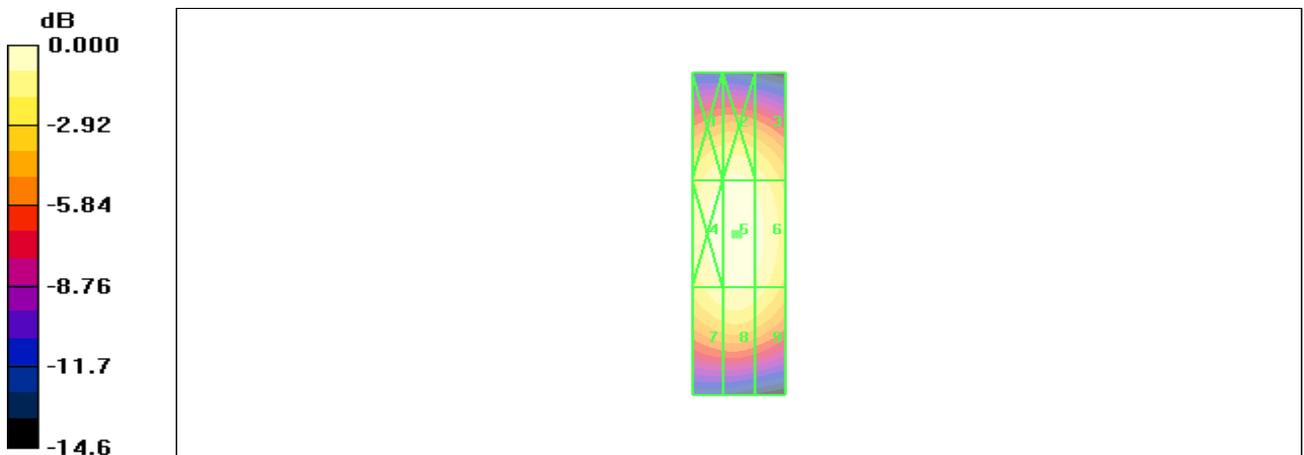
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.472 A/m; Power Drift = -0.005 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.400 M2	0.413 M2	0.387 M2
Grid 4	Grid 5	Grid 6
0.435 M2	0.449 M2	0.422 M2
Grid 7	Grid 8	Grid 9
0.397 M2	0.410 M2	0.384 M2



0 dB = 0.449A/m

Figure 11 System Performance Check 1880MHz_H

ANNEX B: Graph Results

HAC RF E-Field CDMA Cellular High

Date/Time: 9/12/2010 7:50:59 PM

Communication System: CDMA Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5 °C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 72.8 V/m

Probe Modulation Factor = 1.05

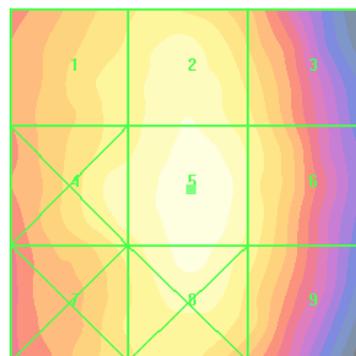
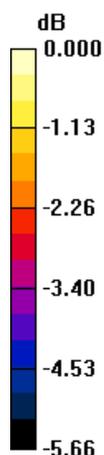
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 96.3 V/m; Power Drift = -0.091 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 66.0 M4	Grid 2 69.9 M4	Grid 3 65.0 M4
Grid 4 69.0 M4	Grid 5 72.8 M4	Grid 6 66.9 M4
Grid 7 65.3 M4	Grid 8 71.1 M4	Grid 9 65.7 M4



0 dB = 72.8V/m

Figure 12 HAC RF E-Field CDMA Cellular Channel 777

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field CDMA Cellular Middle

Date/Time: 9/12/2010 7:46:05 PM

Communication System: CDMA Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 69.5 V/m

Probe Modulation Factor = 1.05

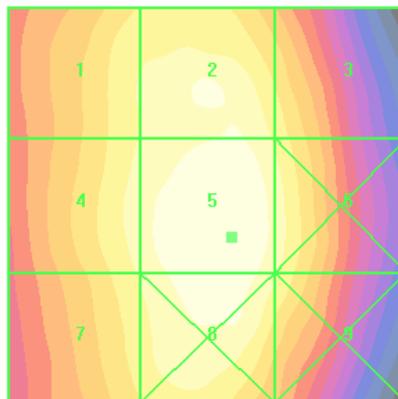
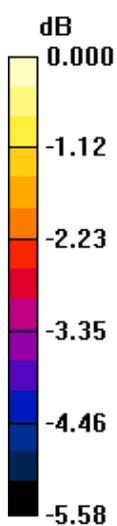
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 89.3 V/m; Power Drift = -0.130 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 64.0 M4	Grid 2 67.3 M4	Grid 3 63.3 M4
Grid 4 65.4 M4	Grid 5 69.5 M4	Grid 6 65.6 M4
Grid 7 64.2 M4	Grid 8 68.4 M4	Grid 9 64.3 M4



0 dB = 69.5V/m

Figure 13 HAC RF E-Field CDMA Cellular Channel 384

HAC RF E-Field CDMA Cellular Low

Date/Time: 9/12/2010 7:55:46 PM

Communication System: CDMA Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 72.3 V/m

Probe Modulation Factor = 1.05

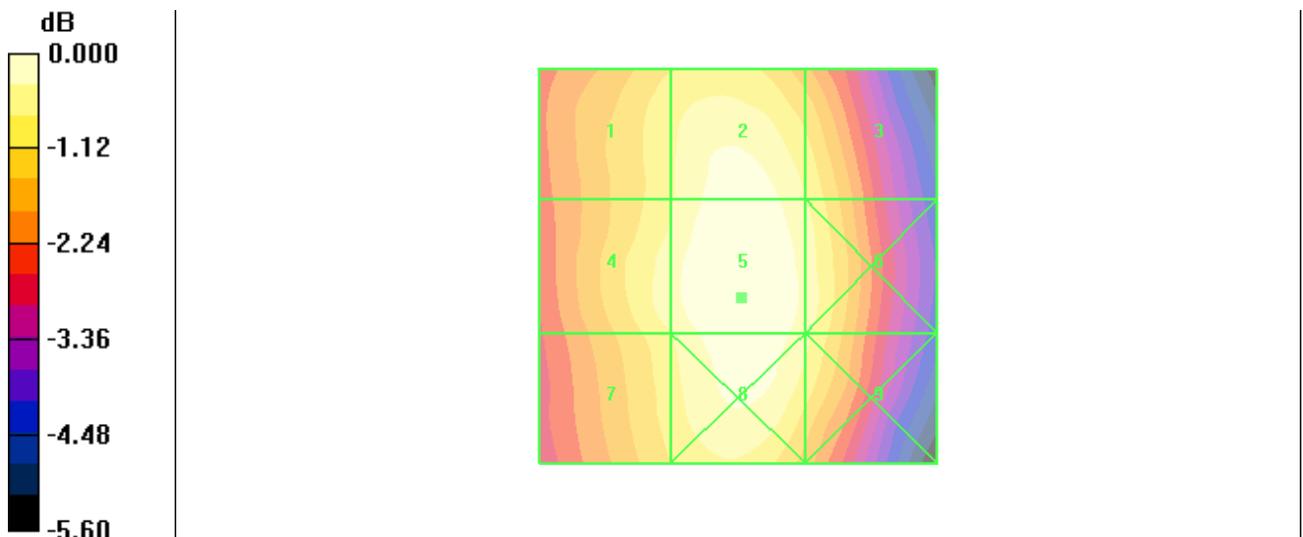
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 91.7 V/m; Power Drift = 0.034 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 66.0 M4	Grid 2 70.7 M4	Grid 3 66.5 M4
Grid 4 68.2 M4	Grid 5 72.3 M4	Grid 6 68.5 M4
Grid 7 66.4 M4	Grid 8 71.0 M4	Grid 9 67.4 M4



0 dB = 72.3V/m

Figure 14 HAC RF E-Field CDMA Cellular Channel 1013

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA Cellular High

Date/Time: 9/12/2010 9:48:02 PM

Communication System: CDMA Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.105 A/m

Probe Modulation Factor = 1.01

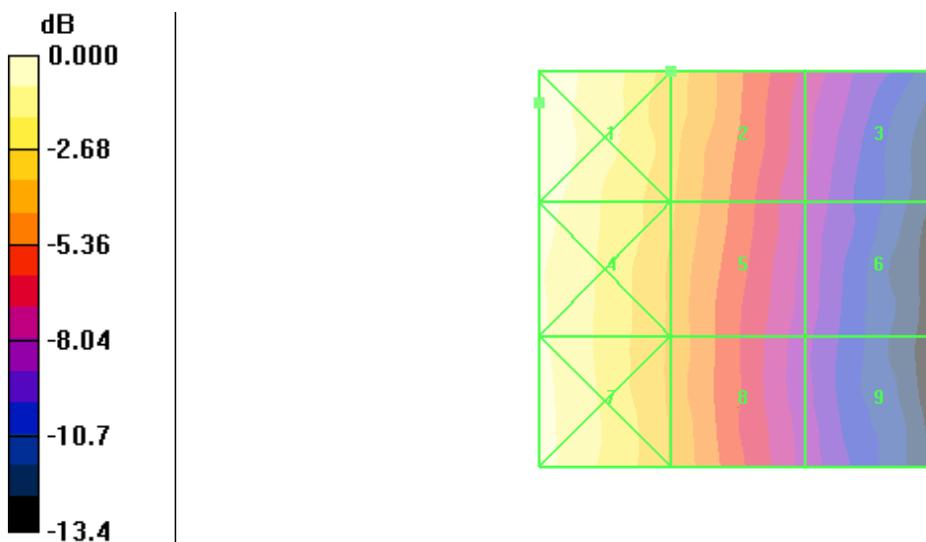
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.078 A/m; Power Drift = -0.152 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.149 M4	Grid 2 0.105 M4	Grid 3 0.064 M4
Grid 4 0.139 M4	Grid 5 0.101 M4	Grid 6 0.059 M4
Grid 7 0.142 M4	Grid 8 0.098 M4	Grid 9 0.057 M4



0 dB = 0.149A/m

Figure 15 HAC RF H-Field CDMA Cellular Channel 777

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA Cellular Middle

Date/Time: 9/12/2010 9:43:05 PM

Communication System: CDMA Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.096 A/m

Probe Modulation Factor = 1.01

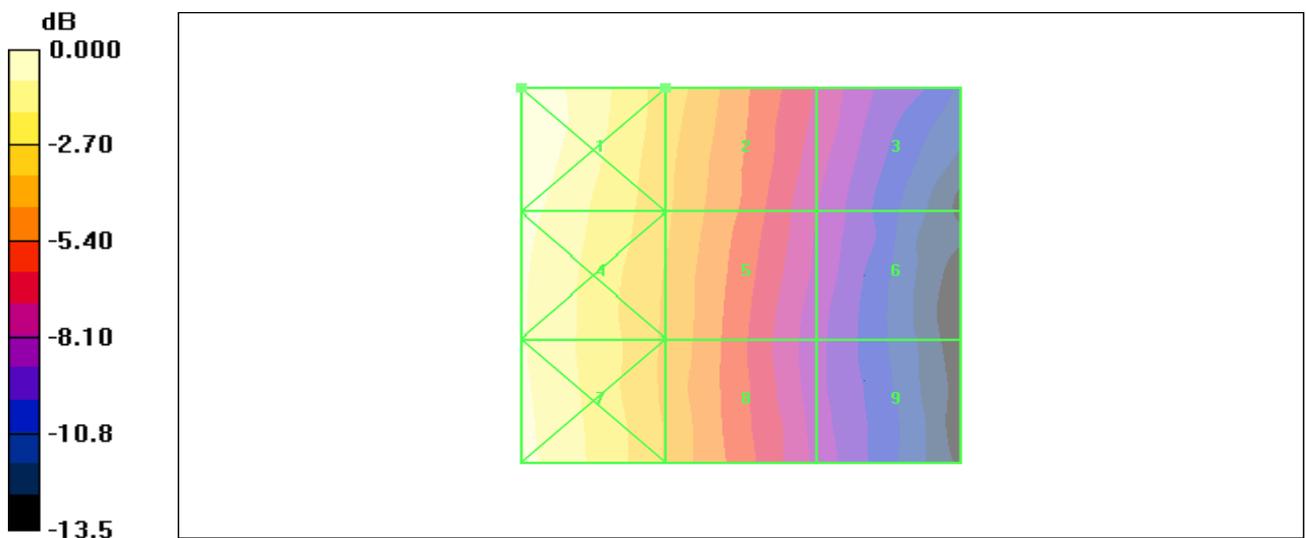
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.073 A/m; Power Drift = -0.015 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.138 M4	Grid 2 0.096 M4	Grid 3 0.060 M4
Grid 4 0.130 M4	Grid 5 0.093 M4	Grid 6 0.055 M4
Grid 7 0.129 M4	Grid 8 0.090 M4	Grid 9 0.053 M4



0 dB = 0.138A/m

Figure 16 HAC RF H-Field CDMA Cellular Channel 384

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA Cellular Low

Date/Time: 9/12/2010 9:38:18 PM

Communication System: CDMA Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 1.01

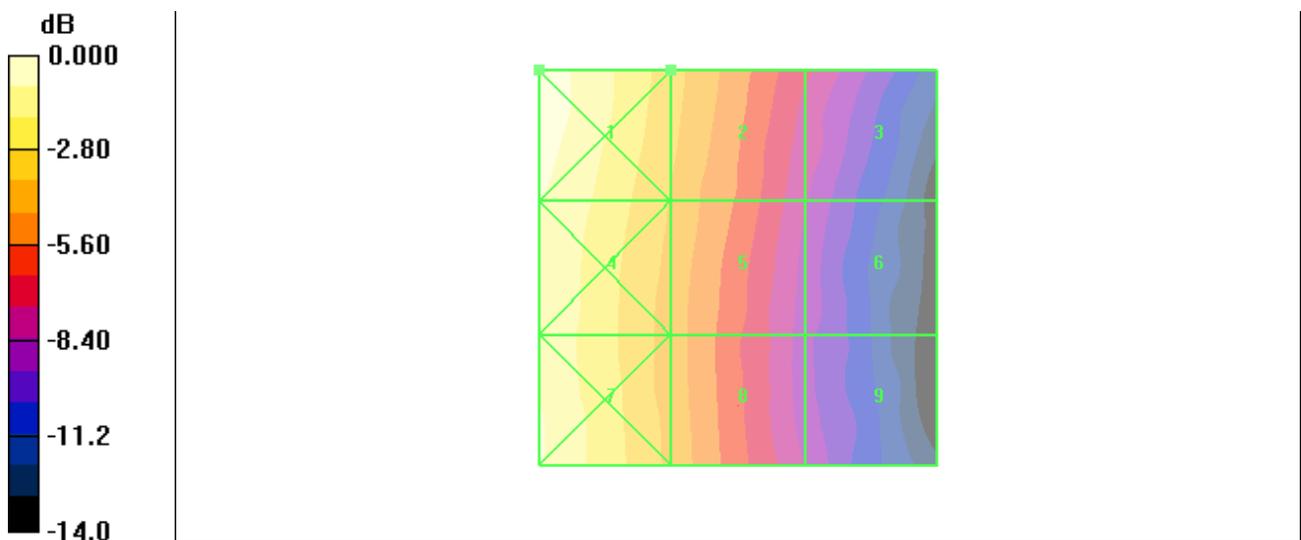
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.072 A/m; Power Drift = 0.010 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.139 M4	Grid 2 0.099 M4	Grid 3 0.063 M4
Grid 4 0.130 M4	Grid 5 0.093 M4	Grid 6 0.055 M4
Grid 7 0.131 M4	Grid 8 0.091 M4	Grid 9 0.055 M4



0 dB = 0.139A/m

Figure 17 HAC RF H-Field CDMA Cellular Channel 1013

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HAC RF E-Field CDMA PCS High

Date/Time: 9/12/2010 8:00:33 PM

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.6 V/m

Probe Modulation Factor = 1.03

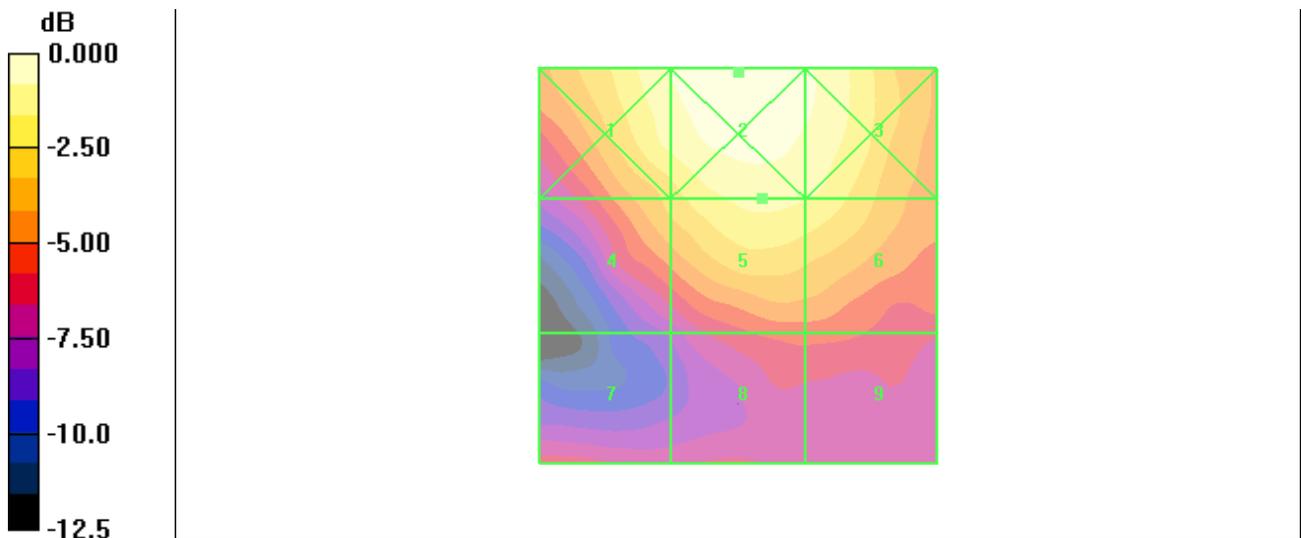
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 41.8 V/m; Power Drift = -0.099 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
41.7 M4	45.4 M4	42.1 M4
Grid 4	Grid 5	Grid 6
32.1 M4	38.6 M4	37.6 M4
Grid 7	Grid 8	Grid 9
22.4 M4	24.4 M4	24.3 M4



0 dB = 45.4V/m

Figure 18 HAC RF E-Field CDMA PCS Channel 1175

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field CDMA PCS Middle

Date/Time: 9/12/2010 8:09:59 PM

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.8 V/m

Probe Modulation Factor = 1.03

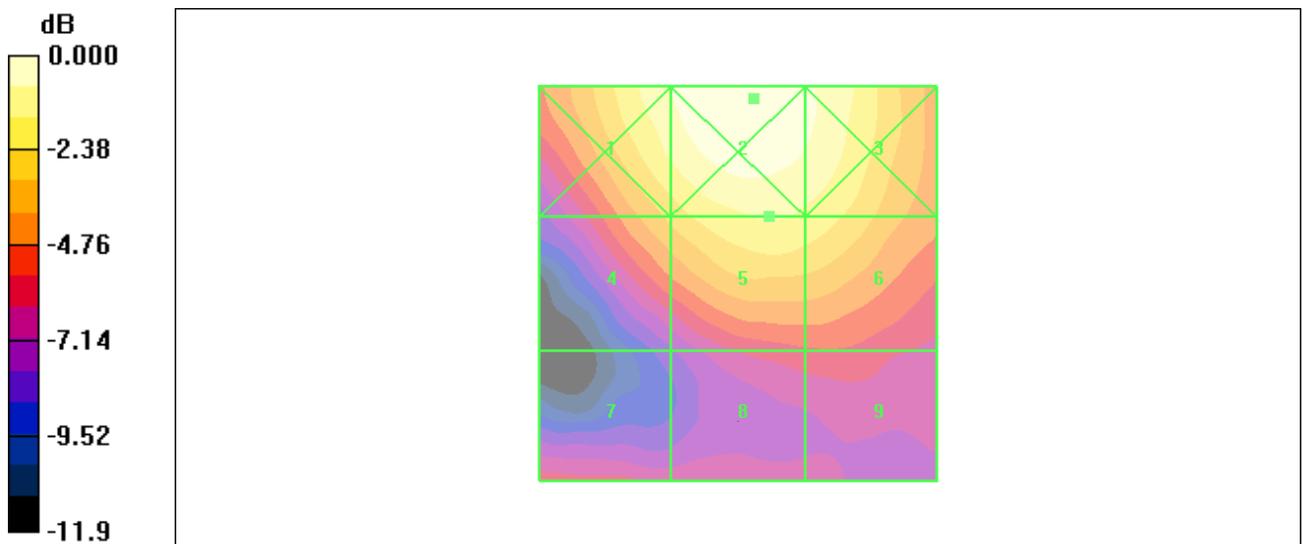
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 38.4 V/m; Power Drift = -0.023 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 42.2 M4	Grid 2 46.2 M4	Grid 3 43.2 M4
Grid 4 32.9 M4	Grid 5 38.8 M4	Grid 6 37.7 M4
Grid 7 23.4 M4	Grid 8 24.1 M4	Grid 9 24.3 M4



0 dB = 46.2V/m

Figure 19 HAC RF E-Field CDMA PCS Channel 600

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field CDMA PCS Low

Date/Time: 9/12/2010 8:05:14 PM

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 39.3 V/m

Probe Modulation Factor = 1.03

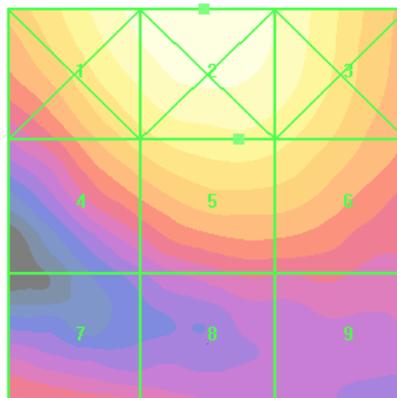
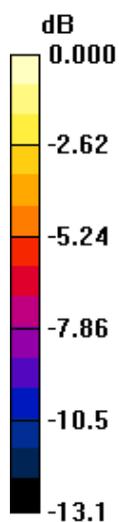
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 38.4 V/m; Power Drift = 0.067 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 46.1 M4	Grid 2 49.3 M4	Grid 3 44.7 M4
Grid 4 34.7 M4	Grid 5 39.3 M4	Grid 6 37.8 M4
Grid 7 25.0 M4	Grid 8 22.7 M4	Grid 9 22.8 M4



0 dB = 49.3V/m

Figure 20 HAC RF E-Field CDMA PCS Channel 25

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA PCS High

Date/Time: 9/12/2010 10:02:43 PM

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.094 A/m

Probe Modulation Factor = 1.00

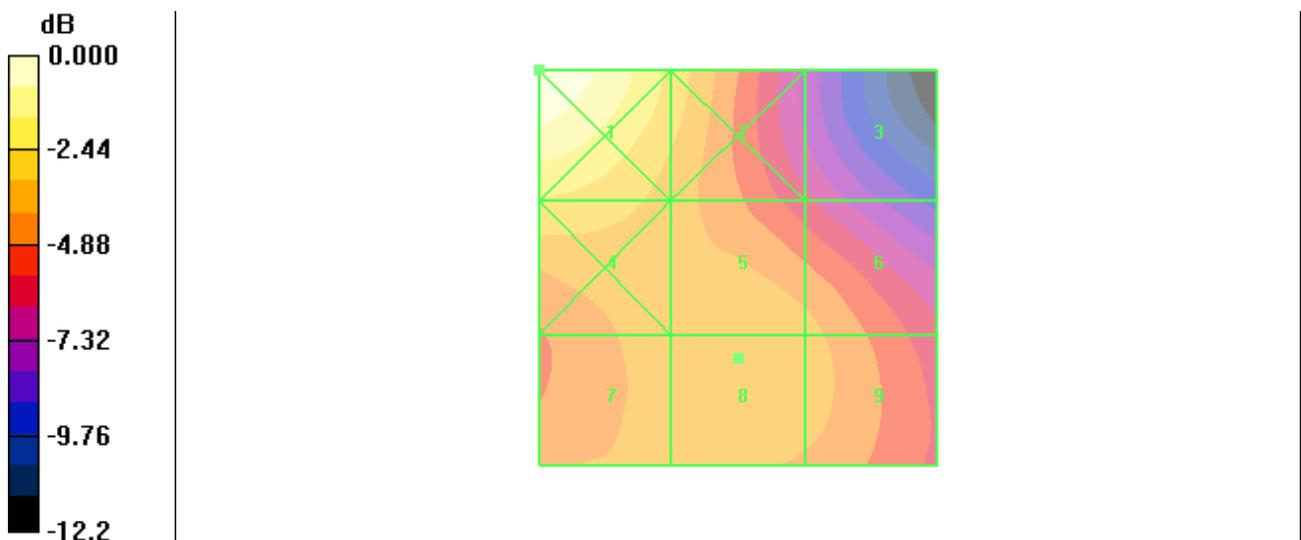
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.099 A/m; Power Drift = 0.001 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.138 M4	Grid 2 0.102 M4	Grid 3 0.067 M4
Grid 4 0.103 M4	Grid 5 0.093 M4	Grid 6 0.089 M4
Grid 7 0.090 M4	Grid 8 0.094 M4	Grid 9 0.090 M4



0 dB = 0.138A/m

Figure 21 HAC RF H-Field CDMA PCS Channel 1175

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA PCS Middle

Date/Time: 9/12/2010 9:53:03 PM

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.093 A/m

Probe Modulation Factor = 1.00

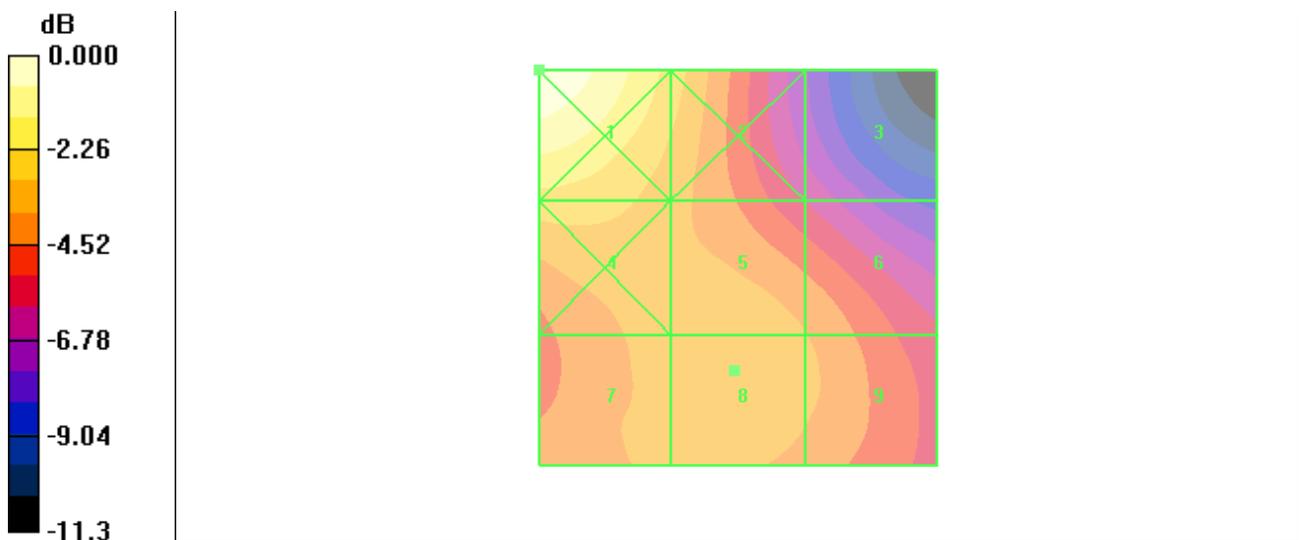
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.096 A/m; Power Drift = 0.050 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.134 M4	Grid 2 0.100 M4	Grid 3 0.067 M4
Grid 4 0.100 M4	Grid 5 0.092 M4	Grid 6 0.087 M4
Grid 7 0.090 M4	Grid 8 0.093 M4	Grid 9 0.089 M4



0 dB = 0.134A/m

Figure 22 HAC RF H-Field CDMA PCS Channel 600

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA PCS Low

Date/Time: 9/12/2010 9:57:53 PM

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 1.00

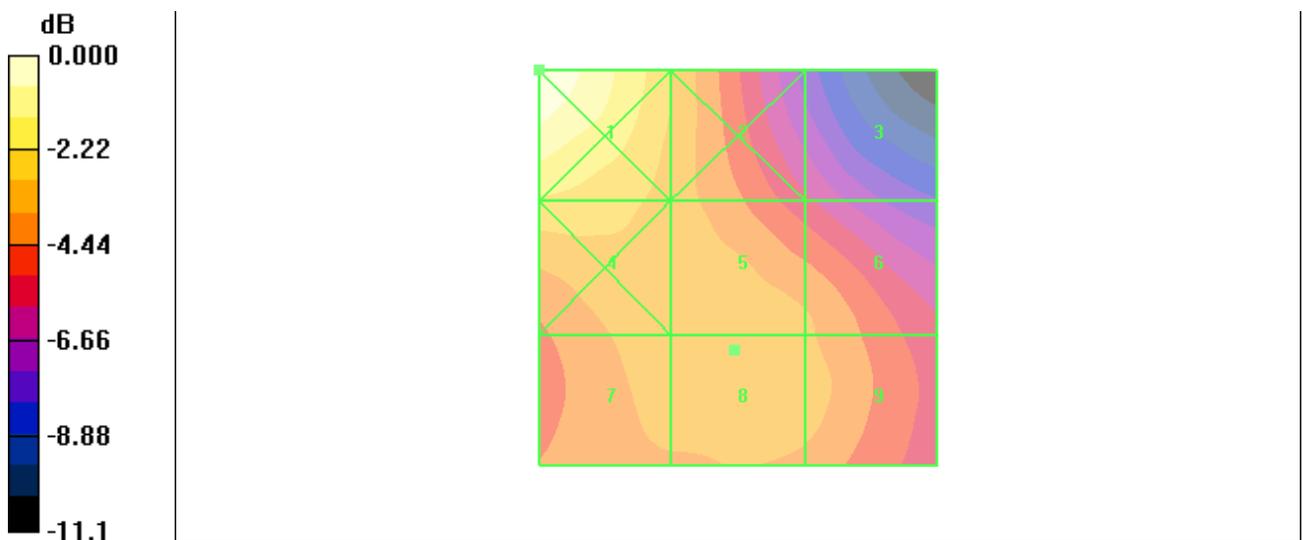
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.104 A/m; Power Drift = -0.116 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.140 M4	Grid 2 0.100 M4	Grid 3 0.073 M4
Grid 4 0.107 M4	Grid 5 0.099 M4	Grid 6 0.093 M4
Grid 7 0.097 M4	Grid 8 0.099 M4	Grid 9 0.095 M4



0 dB = 0.140A/m

Figure 23 HAC RF H-Field CDMA PCS Channel 25

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field CDMA AWS High

Date/Time: 9/12/2010 8:24:14 PM

Communication System: CDMA AWS; Frequency: 1752.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5 °C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 30.8 V/m

Probe Modulation Factor = 1.03

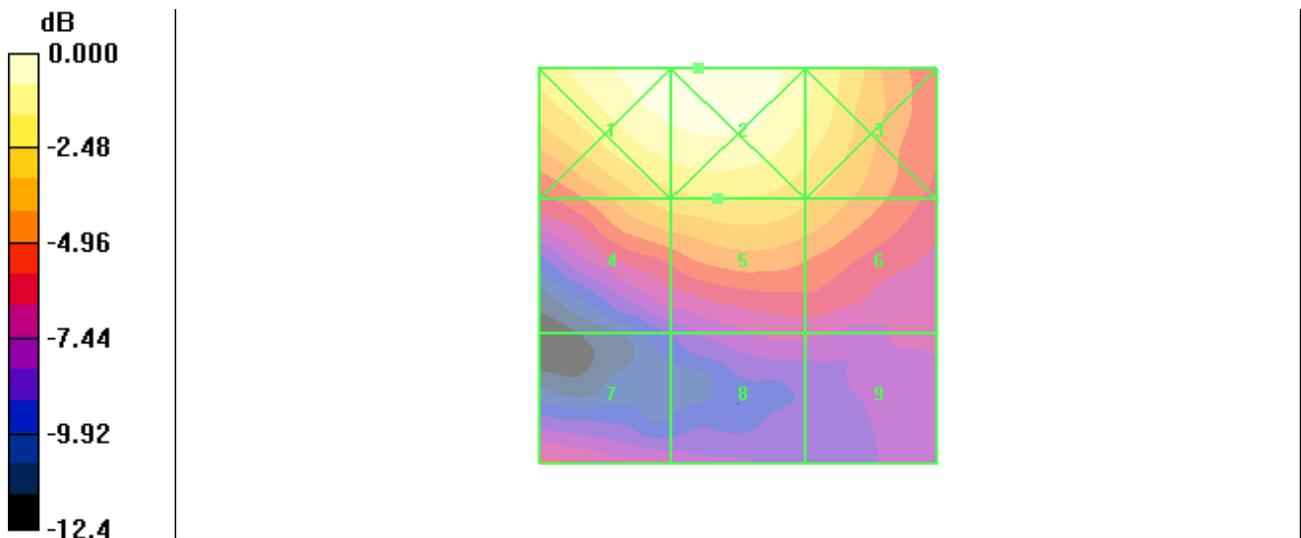
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 29.0 V/m; Power Drift = -0.064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 40.3 M4	Grid 2 41.1 M4	Grid 3 34.8 M4
Grid 4 29.6 M4	Grid 5 30.8 M4	Grid 6 28.5 M4
Grid 7 20.0 M4	Grid 8 18.1 M4	Grid 9 18.1 M4



0 dB = 41.1V/m

Figure 24 HAC RF E-Field CDMA AWS Channel 850

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field CDMA AWS Middle

Date/Time: 9/12/2010 8:14:44 PM

Communication System: CDMA AWS; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.3 V/m

Probe Modulation Factor = 1.03

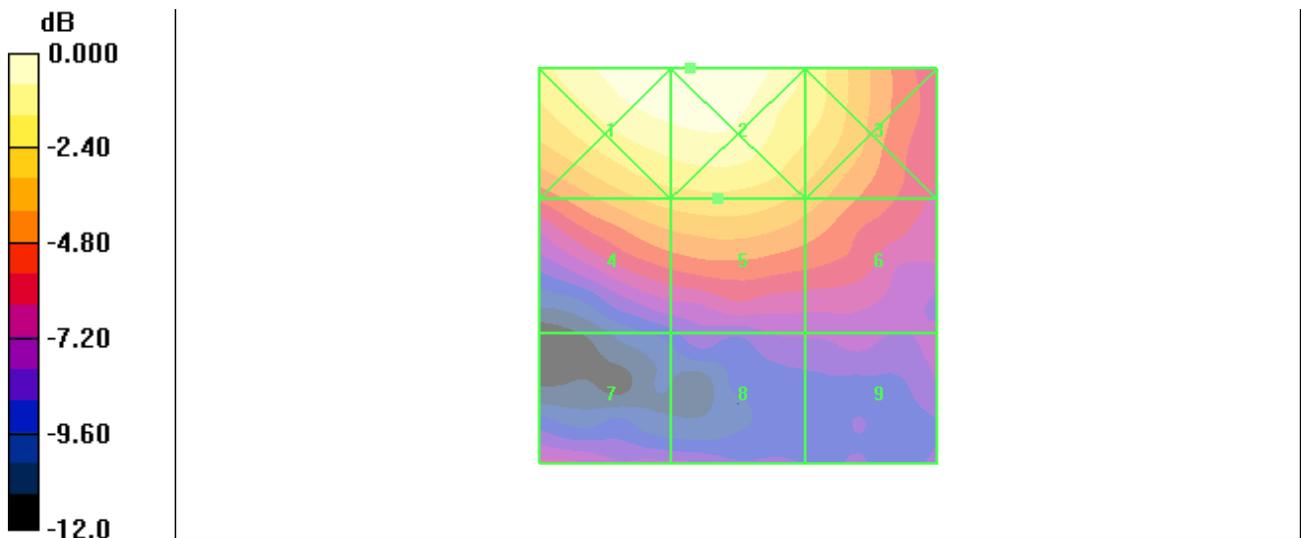
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 28.1 V/m; Power Drift = 0.052 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 42.0 M4	Grid 2 42.3 M4	Grid 3 34.7 M4
Grid 4 30.6 M4	Grid 5 31.3 M4	Grid 6 28.1 M4
Grid 7 19.3 M4	Grid 8 17.3 M4	Grid 9 17.7 M4



0 dB = 42.3V/m

Figure 25 HAC RF E-Field CDMA AWS Channel 450

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF E-Field CDMA AWS Low

Date/Time: 9/12/2010 8:19:27 PM

Communication System: CDMA AWS; Frequency: 1711.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: ER3DV6 - SN2428; ConvF(1, 1, 1); Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 26.6 V/m

Probe Modulation Factor = 1.03

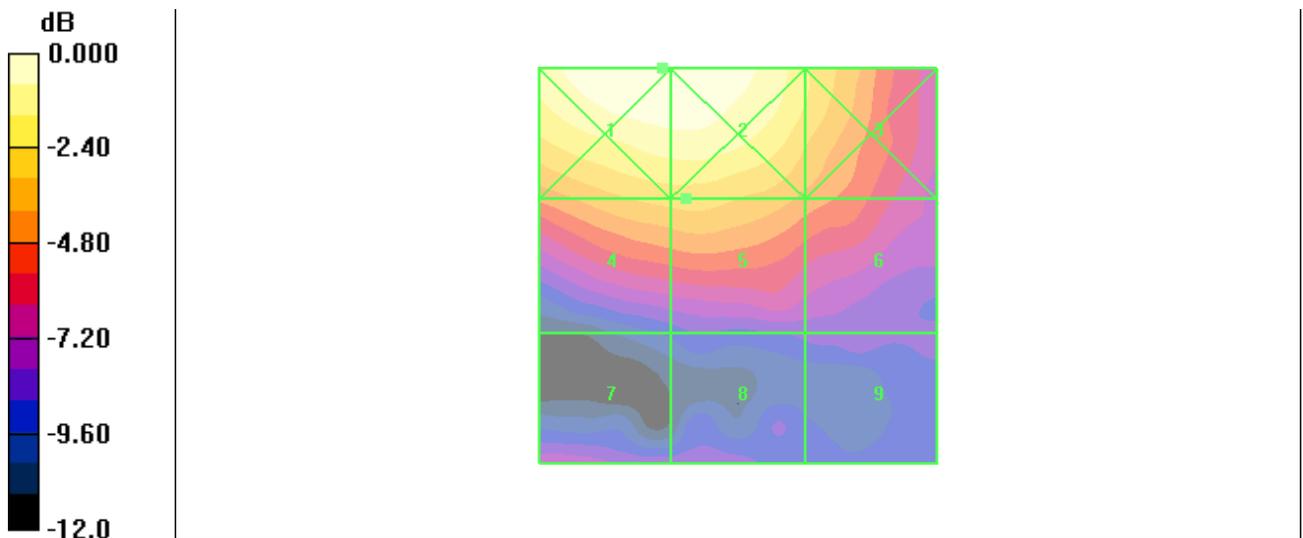
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 23.8 V/m; Power Drift = -0.064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 36.9 M4	Grid 2 36.9 M4	Grid 3 28.5 M4
Grid 4 26.4 M4	Grid 5 26.6 M4	Grid 6 22.7 M4
Grid 7 16.1 M4	Grid 8 14.6 M4	Grid 9 14.3 M4



0 dB = 36.9V/m

Figure 26 HAC RF E-Field CDMA AWS Channel 25

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA AWS High

Date/Time: 9/12/2010 10:07:49 PM

Communication System: CDMA AWS; Frequency: 1752.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.073 A/m

Probe Modulation Factor = 1.00

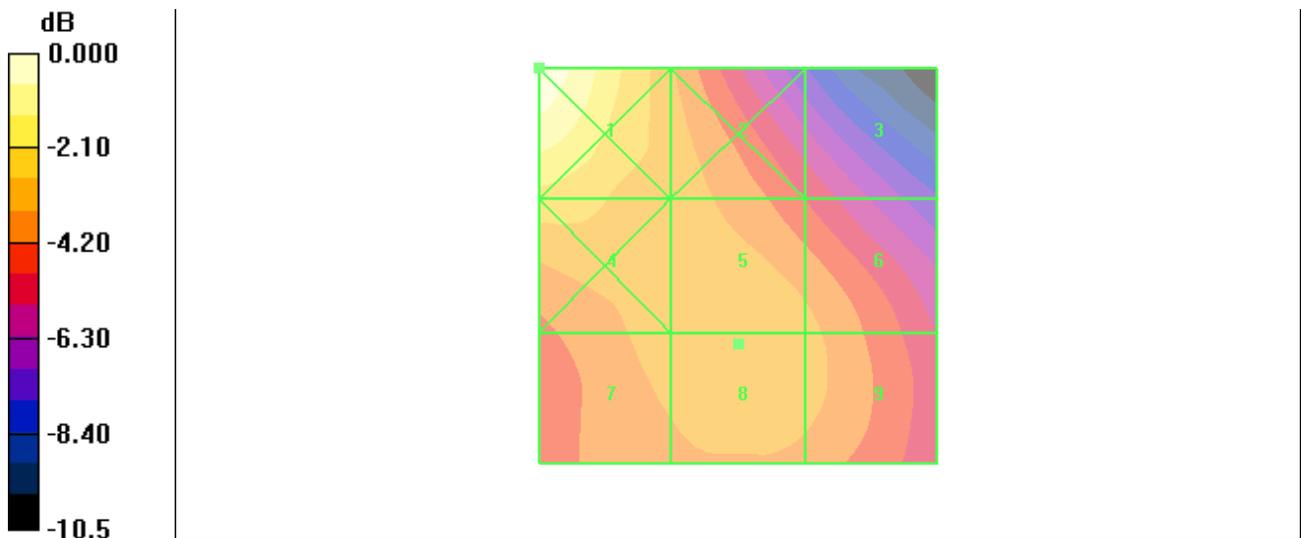
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.078 A/m; Power Drift = 0.166 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.102 M4	Grid 2 0.071 M4	Grid 3 0.058 M4
Grid 4 0.078 M4	Grid 5 0.073 M4	Grid 6 0.070 M4
Grid 7 0.071 M4	Grid 8 0.073 M4	Grid 9 0.070 M4



0 dB = 0.102A/m

Figure 27 HAC RF H-Field CDMA AWS Channel 850

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA AWS Middle

Date/Time: 9/12/2010 10:17:36 PM

Communication System: CDMA AWS; Frequency: 1732.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.074 A/m

Probe Modulation Factor = 1.00

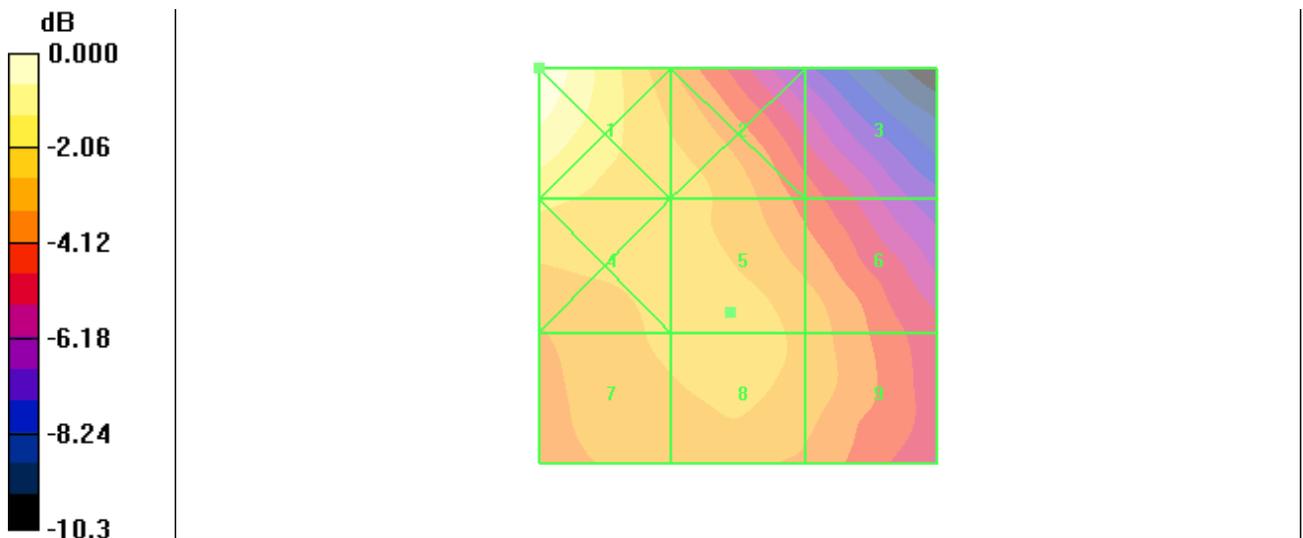
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.081 A/m; Power Drift = 0.072 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.098 M4	Grid 2 0.074 M4	Grid 3 0.059 M4
Grid 4 0.079 M4	Grid 5 0.074 M4	Grid 6 0.069 M4
Grid 7 0.072 M4	Grid 8 0.074 M4	Grid 9 0.070 M4



0 dB = 0.098A/m

Figure 28 HAC RF H-Field CDMA AWS Channel 450

TA Technology (Shanghai) Co., Ltd. Test Report

HAC RF H-Field CDMA AWS Low

Date/Time: 9/12/2010 10:12:42 PM

Communication System: CDMA AWS; Frequency: 1711.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Ambient Temperature: 22.3 °C Liquid Temperature: 21.5°C

Phantom section: RF Section

DASY4 Configuration:

Probe: H3DV6 - SN6260; Calibrated: 10/20/2009

Electronics: DAE4 Sn871; Calibrated: 11/11/2009

Phantom: HAC Test Arch; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.066 A/m

Probe Modulation Factor = 1.00

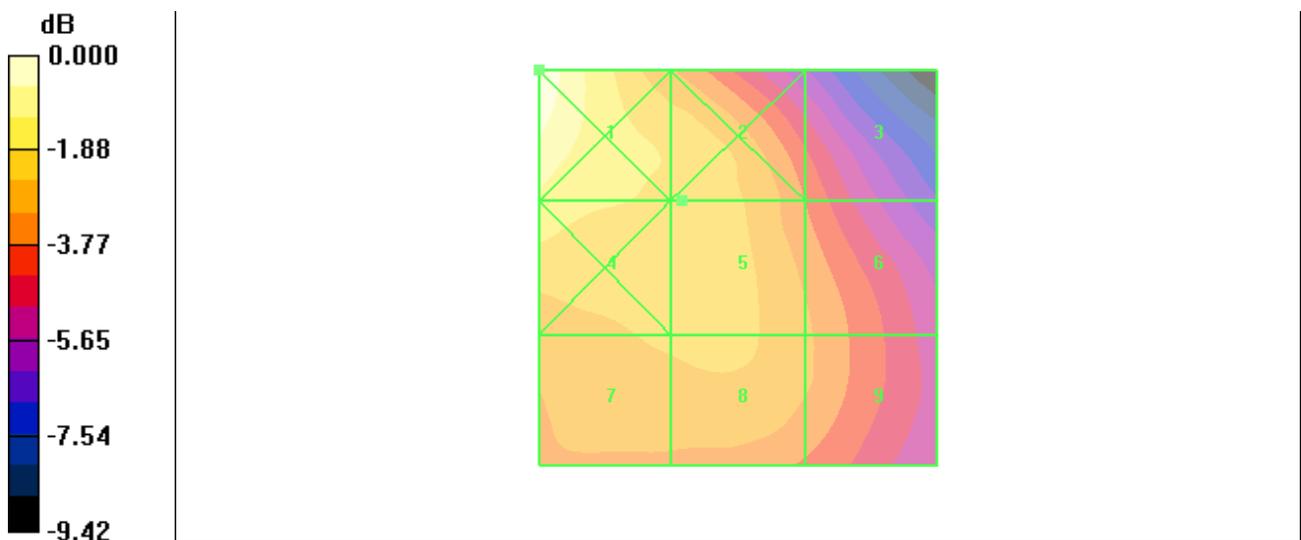
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.073 A/m; Power Drift = -0.154 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.082 M4	Grid 2 0.066 M4	Grid 3 0.053 M4
Grid 4 0.070 M4	Grid 5 0.066 M4	Grid 6 0.058 M4
Grid 7 0.062 M4	Grid 8 0.063 M4	Grid 9 0.058 M4



0 dB = 0.082A/m

Figure 29 HAC RF H-Field CDMA AWS Channel 25

TA Technology (Shanghai) Co., Ltd. Test Report

Report No. RZA2010-1426

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ANNEX C: E-Probe Calibration Certificate

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **TMC**

Certificate No: **ER3-2428_Oct09**

CALIBRATION CERTIFICATE

Object **ER3DV6 - SN:2428**

Calibration procedure(s) **QA CAL-02.v5 and QA CAL-25.v2
Calibration procedure for E-field probes optimized for close near field
evaluations in air**

Calibration date: **October 20, 2009**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration):

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4418B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5086 (20b)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe ER3DV6	SN: 2328	3-Oct-09 (No. ER3-2328_Oct09)	Oct-10
DAE4	SN: 789	19-Dec-08 (No. DAE4-789_Dec08)	Dec-09

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-09 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct-10

Calibrated by:	Name	Function	Signature
	Marcel Fehr	Laboratory Technician	
Approved by:	Katja Pekovic	Technical Manager	

Issued: October 22, 2009

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: ER3-2428_Oct09

Page 1 of 10

Calibration Laboratory of
Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland



S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
S Servizio svizzero di taratura
S Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- *NORM_{x,y,z}*: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- *NORM(f)_{x,y,z}* = *NORM_{x,y,z}* * *frequency_response* (see Frequency Response Chart).
- *DCP_{x,y,z}*: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- *A_{x,y,z}*; *B_{x,y,z}*; *C_{x,y,z}* are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- *Spherical isotropy (3D deviation from isotropy)*: in a locally homogeneous field realized using an open waveguide setup.
- *Sensor Offset*: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- *Connector Angle*: The angle is assessed using the information gained by determining the *NORM_x* (no uncertainty required).

ER3DV6 SN:2428

October 20, 2009

Probe ER3DV6

SN:2428

Manufactured:	September 11, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

TA Technology (Shanghai) Co., Ltd.
Test Report

ER3DV6 SN:2428

October 20, 2009

DASY - Parameters of Probe: ER3DV6 SN:2428

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu V/(V/m)^2$)	1.52	1.59	1.86	$\pm 10.1\%$
DCP (mV) ^A	91.5	93.0	98.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW		X	0.00	0.00	1.00	300	$\pm 1.5\%$
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor $k=2$, which for a normal distribution corresponds to a coverage probability of approximately 95%.

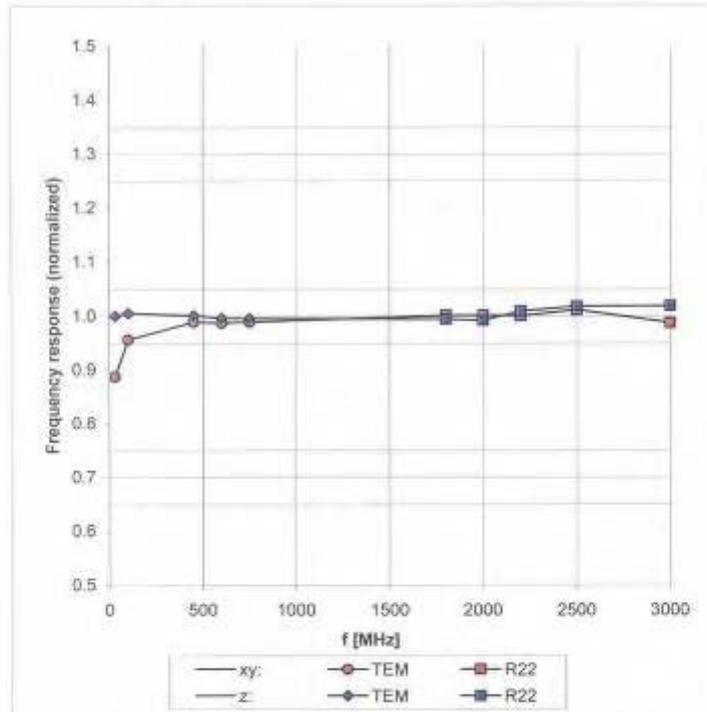
^A numerical linearization parameter: uncertainty not required

ER3DV6 SN:2428

October 20, 2009

Frequency Response of E-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)

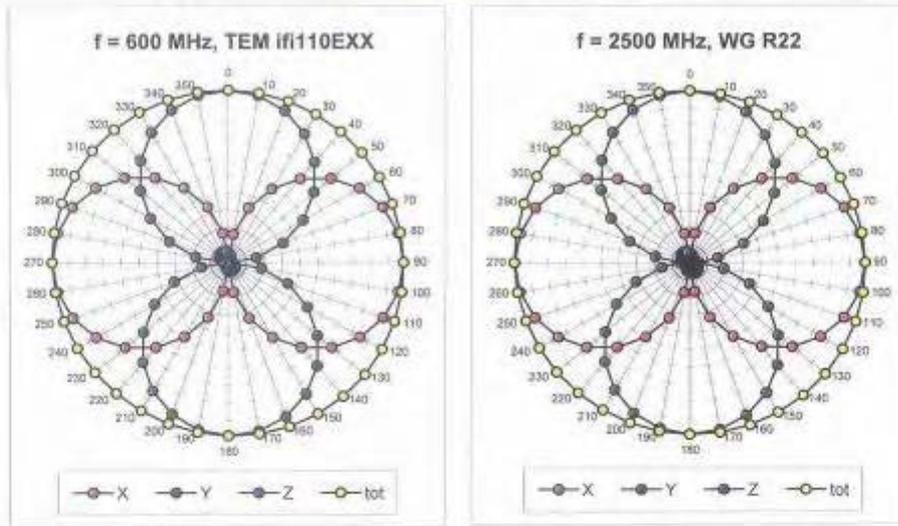


Uncertainty of Frequency Response of E-field: $\pm 6.3\%$ (k=2)

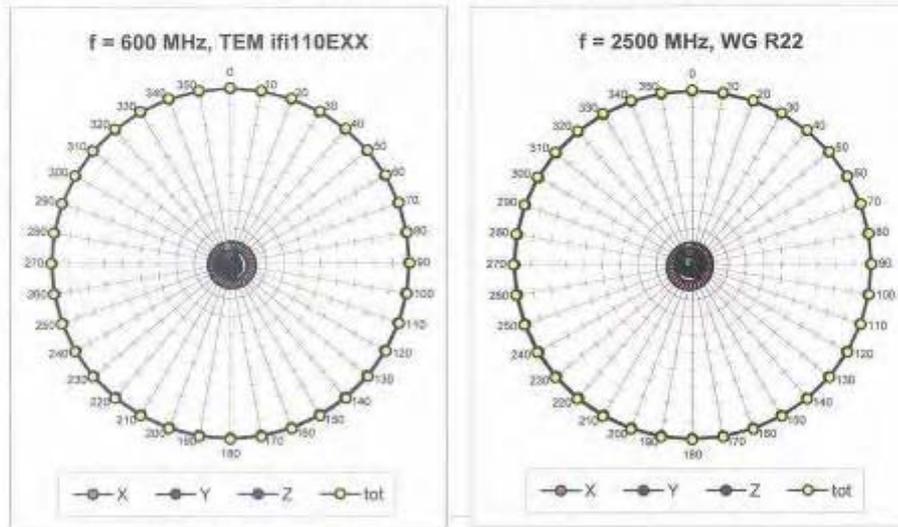
ER3DV6 SN:2428

October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 0^\circ$



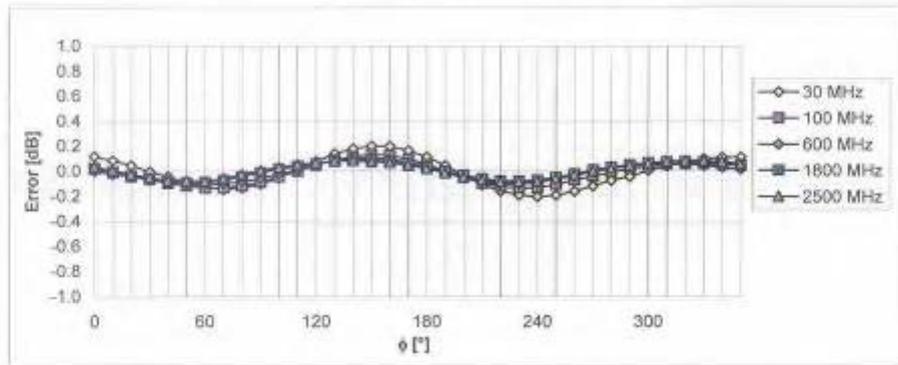
Receiving Pattern (ϕ), $\vartheta = 90^\circ$



ER3DV6 SN:2428

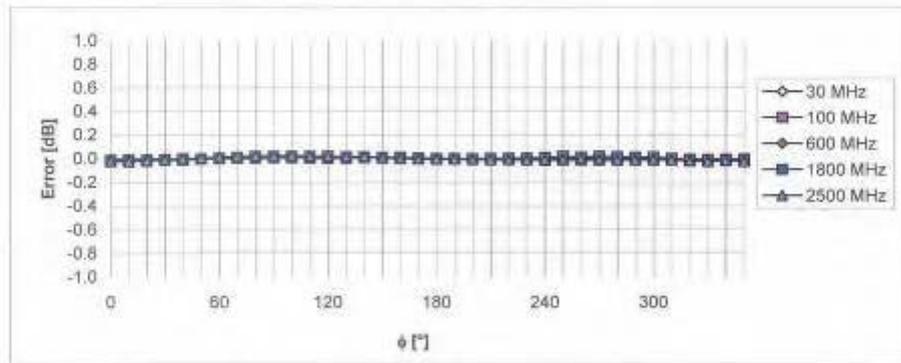
October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 0^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ ($k=2$)

Receiving Pattern (ϕ), $\vartheta = 90^\circ$

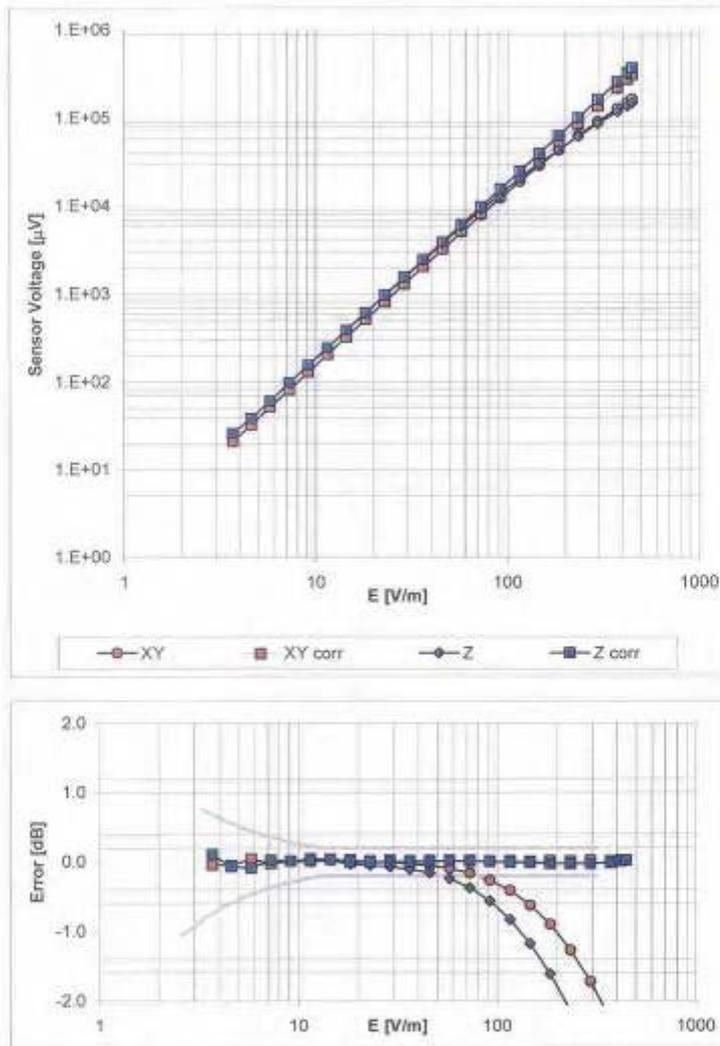


Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ ($k=2$)

ER3DV6 SN:2428

October 20, 2009

Dynamic Range f(E-field) (Waveguide R22, f = 1800 MHz)

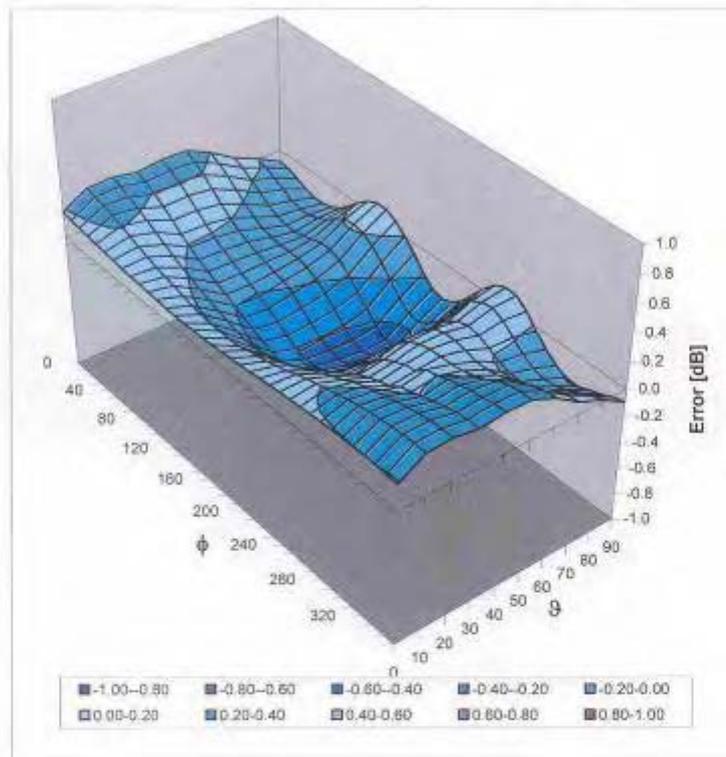


Uncertainty of Linearity Assessment: $\pm 0.6\%$ ($k=2$)

ER3DV6 SN:2428

October 20, 2009

Deviation from Isotropy in Air
Error (ϕ, ϑ), $f = 900$ MHz



Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

ER3DV6 SN:2428

October 20, 2009

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-218.7
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8.0 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

TA Technology (Shanghai) Co., Ltd. Test Report

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ANNEX D: H-Probe Calibration Certificate

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



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The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **TMC**

Certificate No: **H3-6260_Oct09**

CALIBRATION CERTIFICATE

Object: **H3DV6 - SN:6260**

Calibration procedure(s): **QA CAL-03.v5 and QA CAL-25.v2
Calibration procedure for H-field probes optimized for close near field
evaluations in air**

Calibration date: **October 20, 2009**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility; environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41495277	1-Apr-09 (No. 217-01030)	Apr-10
Power sensor E4412A	MY41498087	1-Apr-09 (No. 217-01030)	Apr-10
Reference 3 dB Attenuator	SN: S5054 (3c)	31-Mar-09 (No. 217-01026)	Mar-10
Reference 20 dB Attenuator	SN: S5096 (20b)	31-Mar-09 (No. 217-01028)	Mar-10
Reference 30 dB Attenuator	SN: S5129 (30b)	31-Mar-09 (No. 217-01027)	Mar-10
Reference Probe H3DV6	SN: 6182	3-Oct-09 (No. H3-6182_Oct09)	Oct-10
D4E4	SN: 789	18-Dec-08 (No. D4E4-789_Dec08)	Dec-09
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-09 (in house check Oct-09)	In house check: Oct-11
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct-10

Calibrated by:	Name Marcel Fehr	Function Laboratory Technician	Signature
Approved by:	Name Katja Pokovic	Function Technical Manager	Signature

Issued: October 22, 2009

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Calibration Laboratory of
Schmid & Partner
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Zeughausstrasse 43, 8004 Zurich, Switzerland



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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Glossary:

NORM _{x,y,z}	sensitivity in free space
DCP	diode compression point
CF	crest factor (1/duty_cycle) of the RF signal
A, B, C	modulation dependent linearization parameters
Polarization φ	φ rotation around probe axis
Polarization ϑ	ϑ rotation around an axis that is in the plane normal to probe axis (at measurement center), i.e., $\vartheta = 0$ is normal to probe axis
Connector Angle	information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.

Methods Applied and Interpretation of Parameters:

- NORM_{x,y,z}: Assessed for E-field polarization $\vartheta = 0$ for XY sensors and $\vartheta = 90$ for Z sensor ($f \leq 900$ MHz in TEM-cell; $f > 1800$ MHz: R22 waveguide).
- $X, Y, Z(f)_{a0a1a2} = X, Y, Z_{a0a1a2} \cdot \text{frequency_response}$ (see Frequency Response Chart).
- DCP_{x,y,z}: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- $A_{x,y,z}, B_{x,y,z}, C_{x,y,z}$ are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the X_{a0a1a2} (no uncertainty required).

H3DV6 SN:6260

October 20, 2009

Probe H3DV6

SN:6260

Manufactured:	September 7, 2007
Last calibrated:	December 13, 2007
Recalibrated:	October 20, 2009

Calibrated for DASY Systems

(Note: non-compatible with DASY2 system!)

TA Technology (Shanghai) Co., Ltd.
Test Report

H3DV6 SN:6260

October 20, 2009

DASY - Parameters of Probe: H3DV6 SN:6260

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / $\sqrt{\mu V}$)	a0	2.47E-3	2.49E-3	2.95E-3	± 10.1%
Norm (A/m / $\sqrt{\mu V}$)	a1	-2.97E-5	5.62E-6	-4.47E-5	± 10.1%
Norm (A/m / $\sqrt{\mu V}$)	a2	4.84E-5	4.36E-5	6.01E-5	± 10.1%
DCP (mV) ¹		84.5	90.3	83.9	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dBuV	C	VR mV	Unc (k=2)
10000	CW	0.00	X	0.00	0.00	1.00	300	± 1.5%
			Y	0.00	0.00	1.00	300	
			Z	0.00	0.00	1.00	300	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

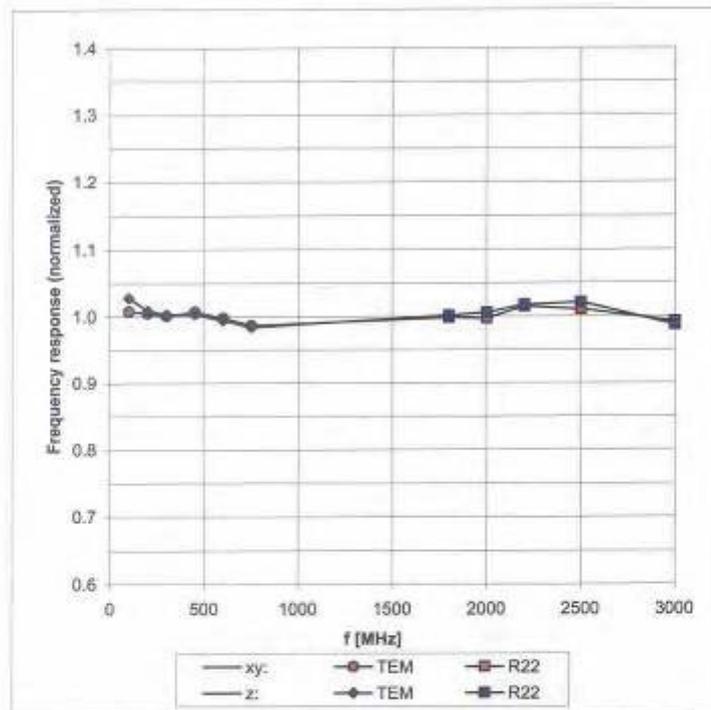
¹ numerical linearization parameter. uncertainty not required

H3DV6 SN:6260

October 20, 2009

Frequency Response of H-Field

(TEM-Cell:ifi110 EXX, Waveguide R22)

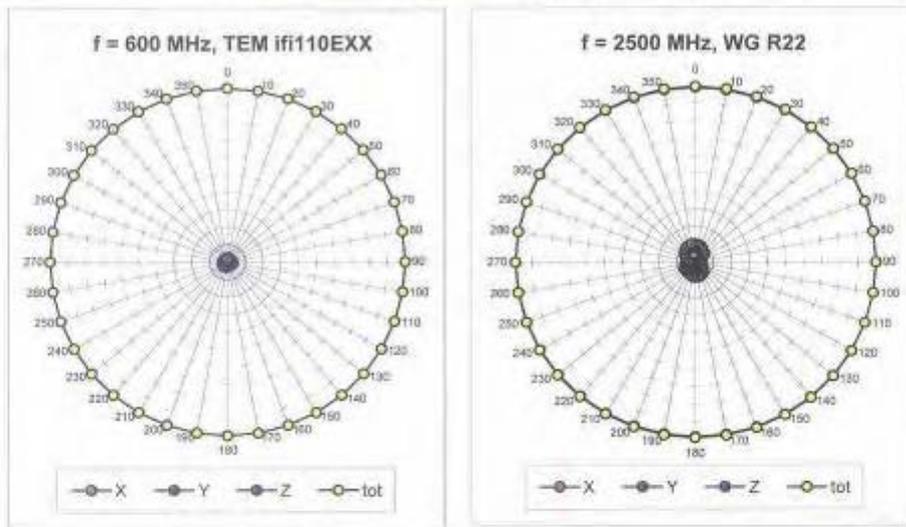


Uncertainty of Frequency Response of H-field: $\pm 6.3\%$ (k=2)

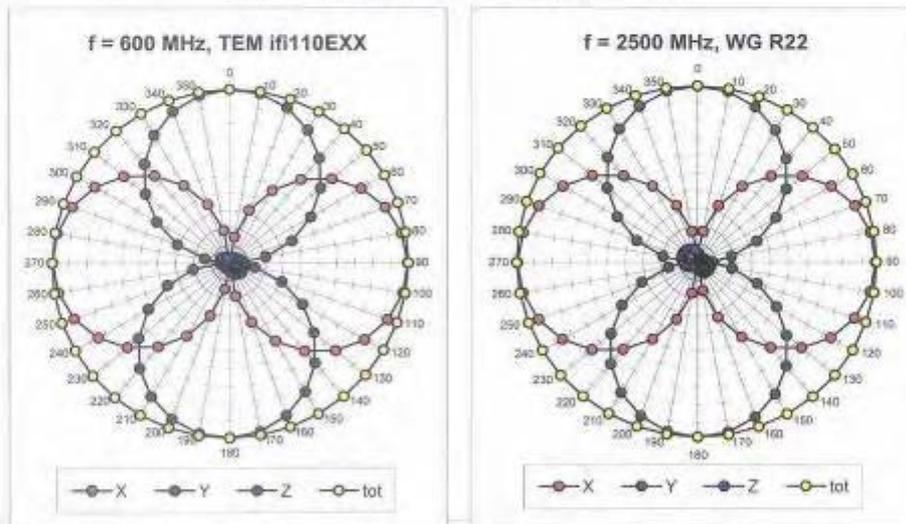
H3DV6 SN:6260

October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 90^\circ$



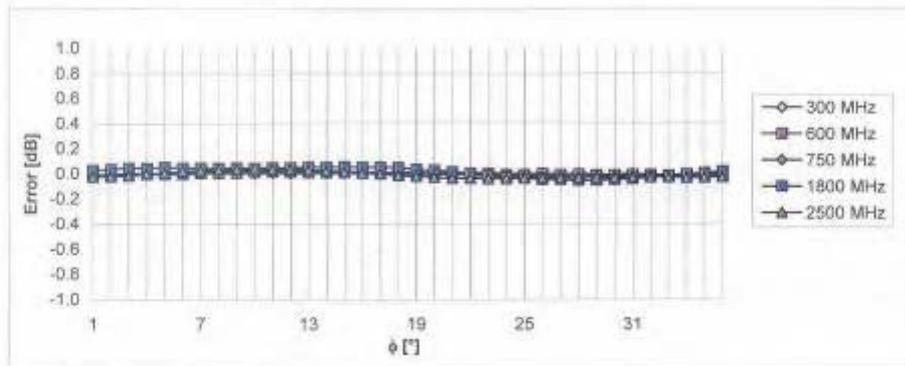
Receiving Pattern (ϕ), $\vartheta = 0^\circ$



H3DV6 SN:6260

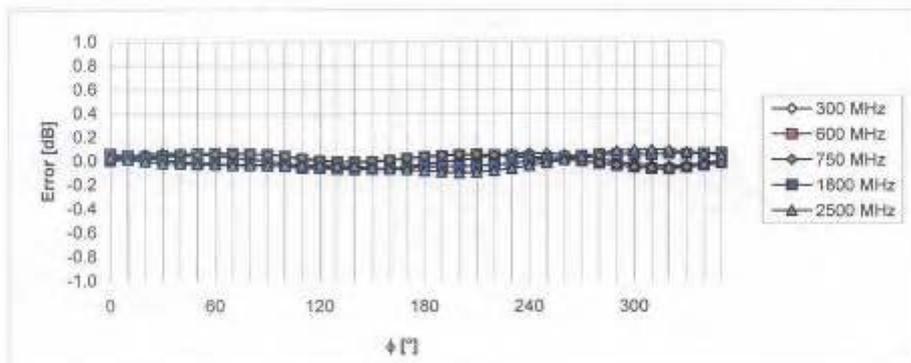
October 20, 2009

Receiving Pattern (ϕ), $\vartheta = 90^\circ$



Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

Receiving Pattern (ϕ), $\vartheta = 0^\circ$

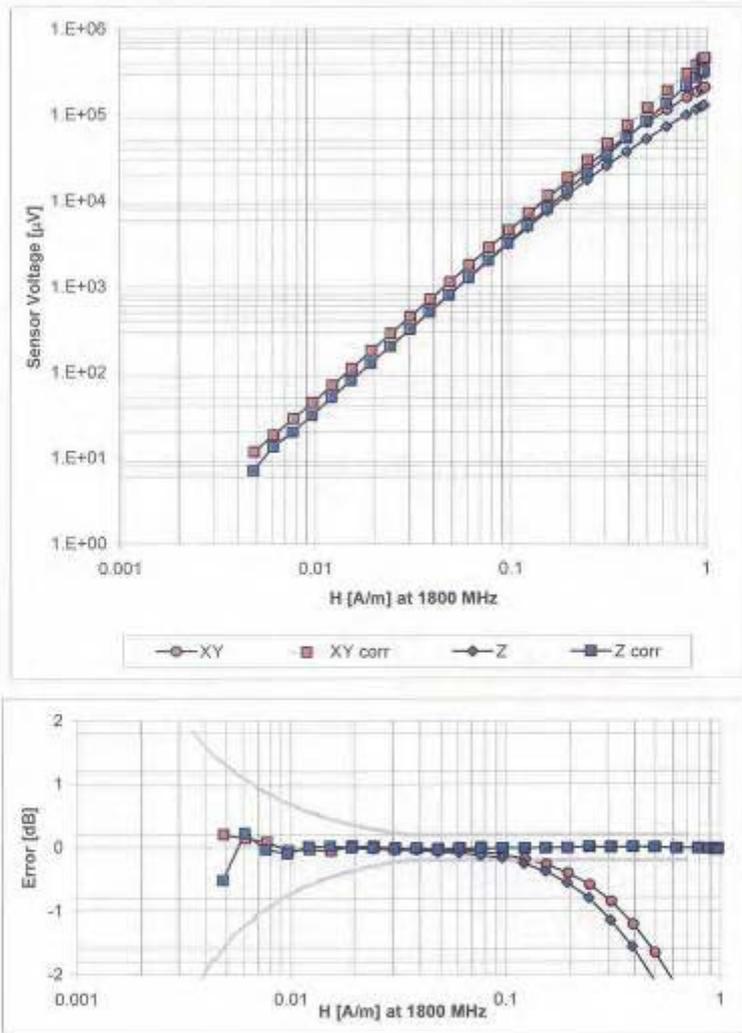


Uncertainty of Axial Isotropy Assessment: $\pm 0.5\%$ (k=2)

H3DV6 SN:6260

October 20, 2009

Dynamic Range f(H-field)
(Waveguide R22, f = 1800 MHz)

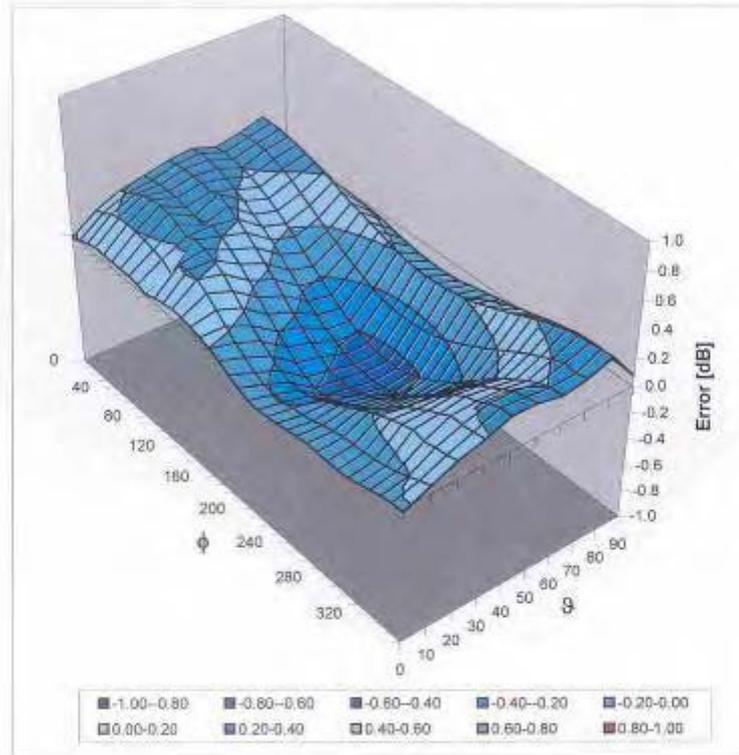


Uncertainty of Linearity Assessment: $\pm 0.6\%$ (k=2)

H3DV6 SN:6260

October 20, 2009

Deviation from Isotropy in Air
Error (ϕ, ϑ), $f = 900$ MHz



Uncertainty of Spherical Isotropy Assessment: $\pm 2.6\%$ ($k=2$)

H3DV6 SN:6260

October 20, 2009

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	-154.1
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6.0 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

TA Technology (Shanghai) Co., Ltd. Test Report

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ANNEX E: CD835V3 Dipole Calibration Certificate (SN: 1149)

**Calibration Laboratory of
Schmid & Partner
Engineering AG**
Zeughausstrasse 43, 8004 Zurich, Switzerland



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Accreditation No.: **SCS 108**

Client **Auden**

Certificate No: **CD835V3-1149_Jan10**

CALIBRATION CERTIFICATE

Object	CD835V3 - SN: 1149		
Calibration procedure(s)	QA CAL-20.v5 Calibration procedure for dipoles in air		
Calibration date:	January 12, 2010		
<p>This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.</p> <p>Calibration Equipment used (M&TE critical for calibration)</p>			
Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-09 (No. 217-01086)	Oct-10
Power sensor HP 8481A	US37292783	06-Oct-09 (No. 217-01086)	Oct-10
Probe ER3DV6	SN: 2336	30-Dec-09 (No. ER3-2336_Dec09)	Dec-10
Probe H3DV6	SN: 6065	30-Dec-09 (No. H3-6065_Dec09)	Dec-10
DAE4	SN: 781	30-Nov-09 (No. DAE4-781_Nov09)	Nov-10
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct-10
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11
Calibrated by:	Name Claudio Leubler	Function Laboratory Technician	Signature Issued: January 19, 2010
Approved by:	Katja Pokovic	Technical Manager	

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Accreditation No.: SCS 108

References

- [1] ANSI-C63.19-2006
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2007
American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- **Coordinate System:** y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are selected to be at a distance of 10 mm above the top edge of the dipole arms.
- **Measurement Conditions:** Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- **Antenna Positioning:** The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- **Feed Point Impedance and Return Loss:** These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminated by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- **E-field distribution:** E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- **H-field distribution:** H-field is measured with an isotropic H-field probe with 100mW forward power to the antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the feed point.

TA Technology (Shanghai) Co., Ltd.

Test Report

1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V5.2 B157
DASY PP Version	SEMCAD X	V14.0 B57
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	835 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

2 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.465 A/m

Uncertainty for H-field measurement: 8.2% (k=2)

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end-	100 mW forward power	170.7 V/m
Maximum measured above low end	100 mW forward power	162.6 V/m
Averaged maximum above arm	100 mW forward power	166.7 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

3 Appendix

3.1 Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.4 dB	(43.4 - j12.6) Ohm
835 MHz	25.5 dB	(49.5 + j5.3) Ohm
900 MHz	16.6 dB	(55.7 - j14.8) Ohm
950 MHz	23.5 dB	(45.4 + j4.4) Ohm
960 MHz	16.8 dB	(48.6 + j14.4) Ohm

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

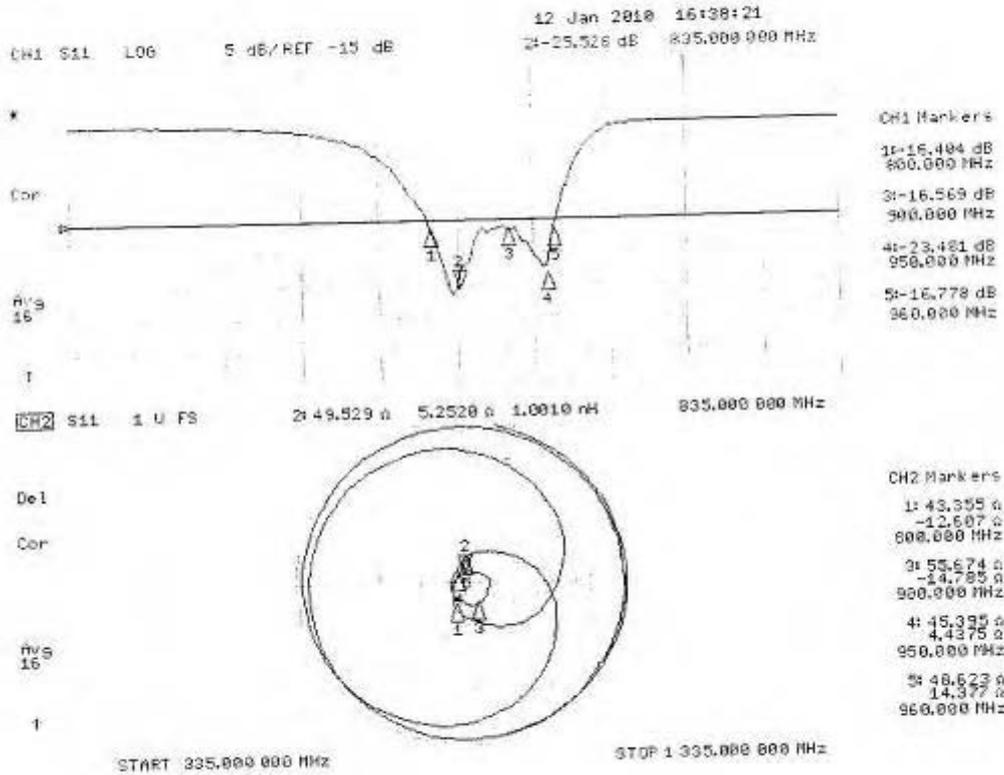
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

3.3 Measurement Sheets

3.3.1 Return Loss and Smith Chart



3.3.2 DASY4 H-field Result

Date/Time: 12.01.2010 12:23:55

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1149_100112_H_CL

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1149

Communication System: CW; Frequency: 835 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 30.11.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY5, V5.2 Build 157; SEMCAD X Version 14.0 Build 57

Dipole H-Field measurement @ 835MHz/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.465 A/m

Probe Modulation Factor = 1

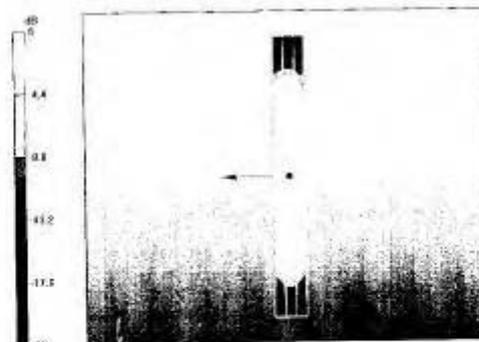
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.495 A/m; Power Drift = -0.012 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.395 M4	Grid 2 0.411 M4	Grid 3 0.381 M4
Grid 4 0.446 M4	Grid 5 0.465 M4	Grid 6 0.433 M4
Grid 7 0.394 M4	Grid 8 0.414 M4	Grid 9 0.388 M4



0 dB = 0.465 A/m

3.3.3 DASY4 E-field Result

Date/Time: 12.01.2010 14:55:38

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1149_100112_E_CL

DUT: HAC-Dipole 835 MHz; Type: D835V3; Serial: 1149

Communication System: CW; Frequency: 835 MHz

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 30.11.2009
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY5, V5.2 Build 157; SEMCAD X Version 14.0 Build 57

Dipole E-Field measurement @ 835MHz/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 170.7 V/m

Probe Modulation Factor = 1

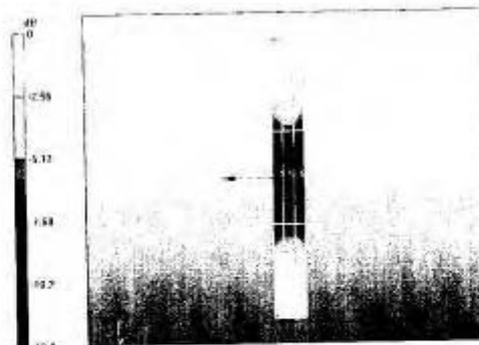
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 108.8 V/m; Power Drift = 0.013 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 158.8 M4	Grid 2 162.6 M4	Grid 3 157.4 M4
Grid 4 86.2 M4	Grid 5 88.2 M4	Grid 6 85.4 M4
Grid 7 158.6 M4	Grid 8 170.7 M4	Grid 9 169.5 M4



0 dB = 170.7V/m